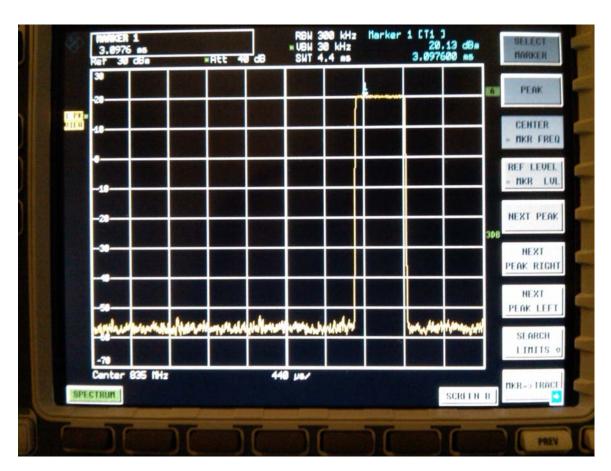
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 1 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

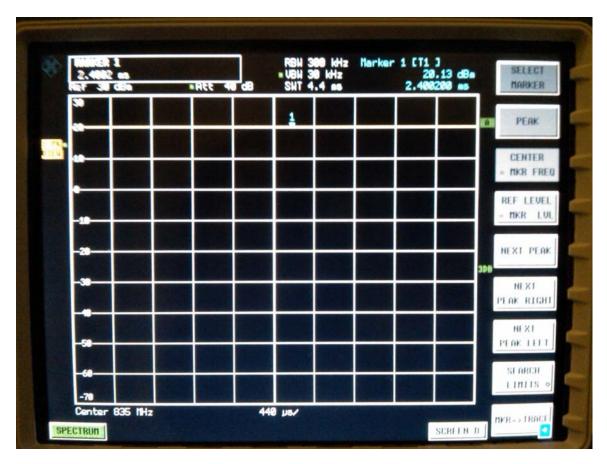
Annex A: Measurement data and plots

A.1 Spectrum analyser plots: GSM/CDMA/UMTS, CW, 80%AM, signals



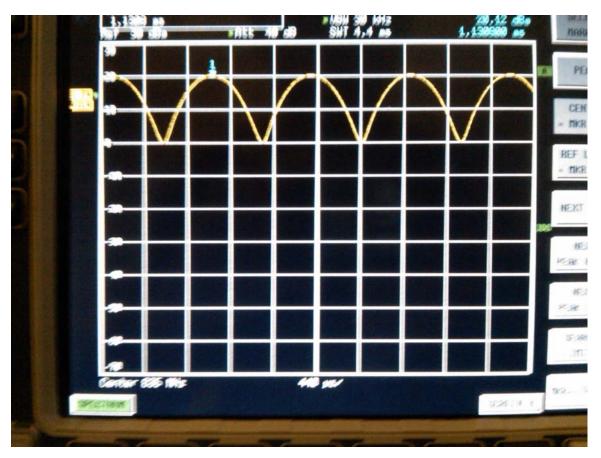
GSM 835 MHz

Testing Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 2 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	J W



CW 835 MHz

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 3 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW		CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



AM 80% 835 MHz

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 4 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



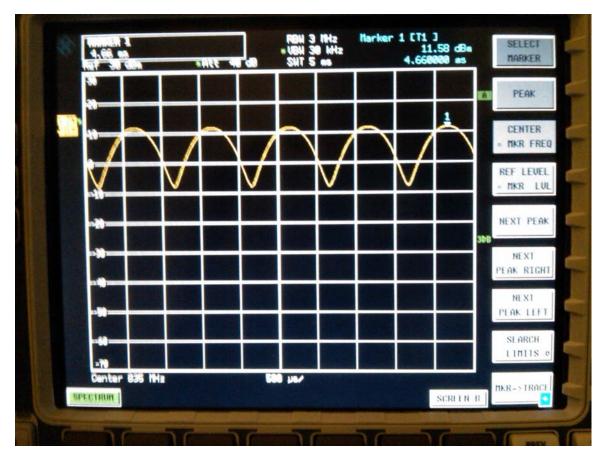
CDMA 835 MHz

Testing Service	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH700	CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	J W

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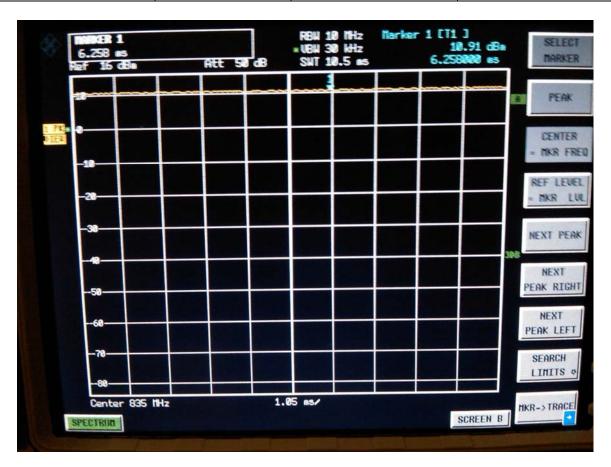
CW 835 MHz

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 6 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



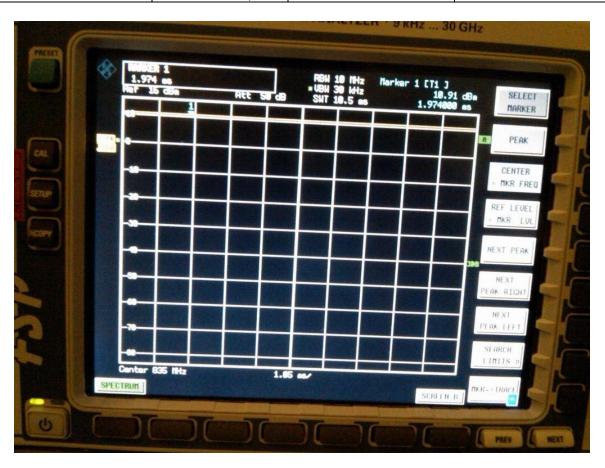
AM 80% 835 MHz

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 7 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



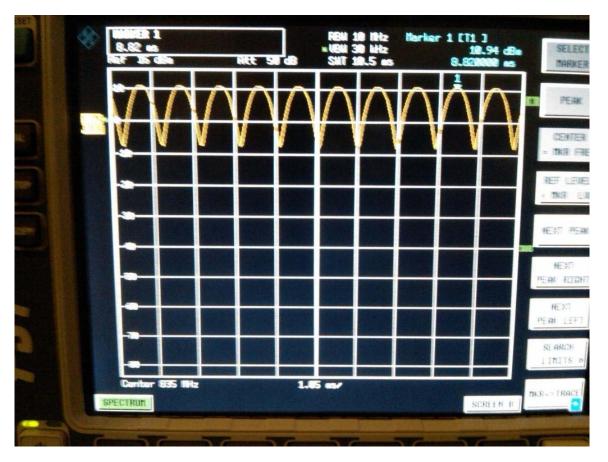
UMTS 835 MHz

Testing Services	Report for the Black	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



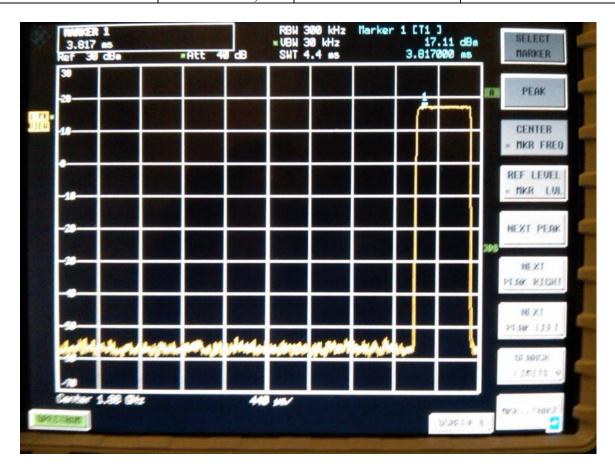
CW 835 MHz

Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 9 (286)
Dates of Test	Report No	FCC ID	
Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Annex A to Hearing Report for the Black RDH71CW/RDP71UW Dates of Test	Annex A to Hearing Aid Compatibility RF Emis Report for the BlackBerry® Smartphone mode RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 Report No RTS-2605-1102-02A	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 RTS-2605-1102-02A



AM 80% 835 MHz

Testing Service	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



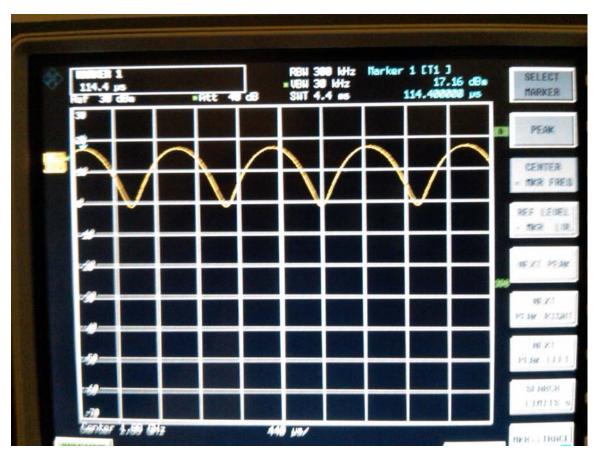
GSM 1880 MHz

Testing Services	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 11 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



CW 1880 MHz

Testing Services™	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH700 L6ARDP70U	



AM 80 % 1880 MHz

Testing Services™	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



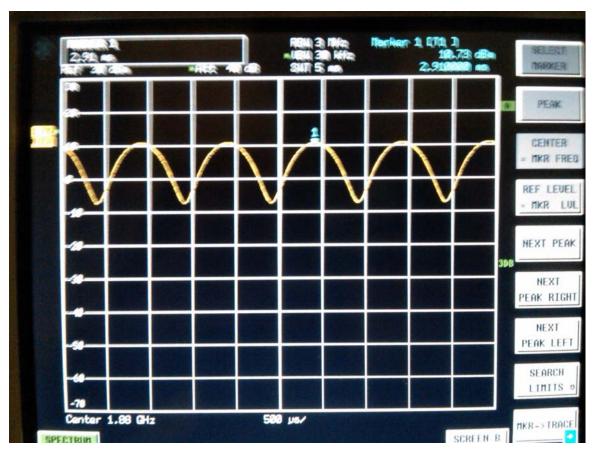
CDMA 1880 MHz

Testing Service		Aid Compatibility RF Emis Berry® Smartphone mode		Page 14 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW		
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



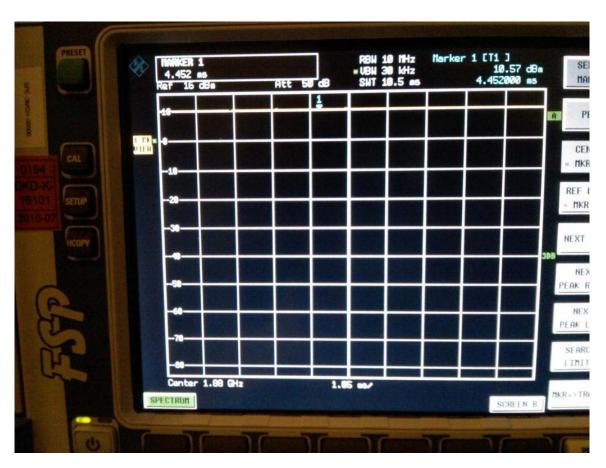
CW 1880 MHz

Testing Services [™]	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	



AM 80 % 1880 MHz

Testing Services [™]	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



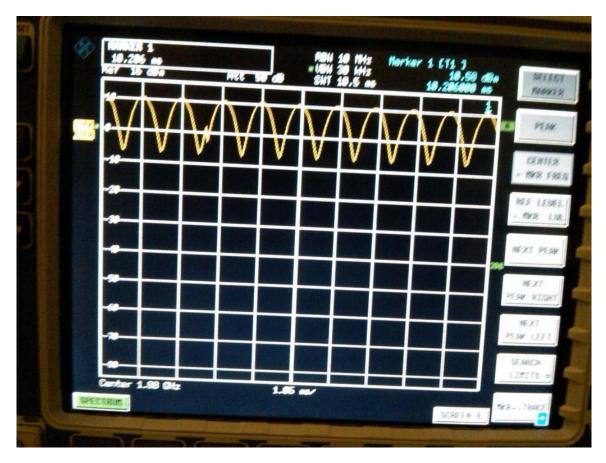
UMTS 1880 MHz

Testing Services™	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	



CW 1880 MHz

Testing Services™		Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			• •
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



AM 80 % 1880 MHz

Testing Services™	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	

A.2 Dipole validation and probe modulation factor plots

Testing Services™	Report for the Black	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Date/Time: 1/12/2011 12:39:57 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 110.5 V/m; Power Drift = -0.014 dB Maximum value of Total (measured) = 168.0 V/m

Testing Services™	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 169.7 V/m

Probe Modulation Factor = 1.00

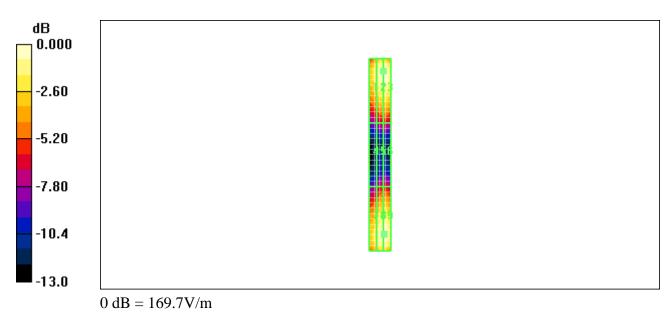
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 110.5 V/m; Power Drift = -0.014 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V	V/m	
Grid 1	Grid 2	Grid 3
143.5 M4	169.7 M4	169.7 M4
Grid 4	Grid 5	Grid 6
70.5 M4	84.9 M4	85.0 M4
Grid 7	Grid 8	Grid 9
137.9 M4	166.2 M4	166.5 M4

Testing Services™	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	



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Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 23 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 11:06:12 AM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: GSM 850; Frequency: 835 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 39.7 V/m; Power Drift = -0.029 dB Maximum value of Total (measured) = 54.5 V/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 24 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011	Teb. 28-Mar. 01, 2011 L6ARDP70U		

CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 55.1 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

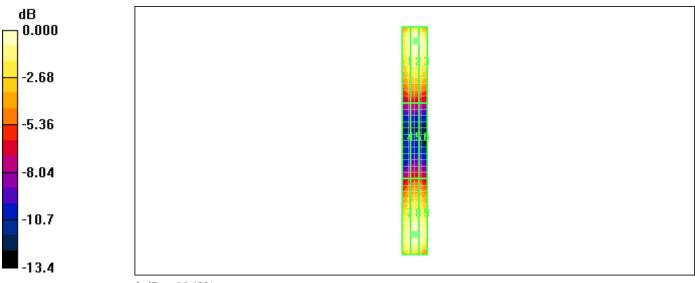
Reference Value = 39.7 V/m; Power Drift = -0.029 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in	n V/m	
Grid 1	Grid 2	Grid 3
52.0 M4	55.1 M4	54.5 M4
Grid 4	Grid 5	Grid 6
27.5 M4	28.6 M4	28.1 M4
Grid 7	Grid 8	Grid 9
52.3 M4	53.6 M4	53.2 M4

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Testing Services™	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 55.1 V/m

Testing Services ^{**}	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 26 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 11:22:25 AM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_CW_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 115.7 V/m; Power Drift = 0.021 dB Maximum value of Total (measured) = 158.6 V/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 27 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011	Feb. 28-Mar. 01, 2011 L6ARDP70U		

CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 159.9 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

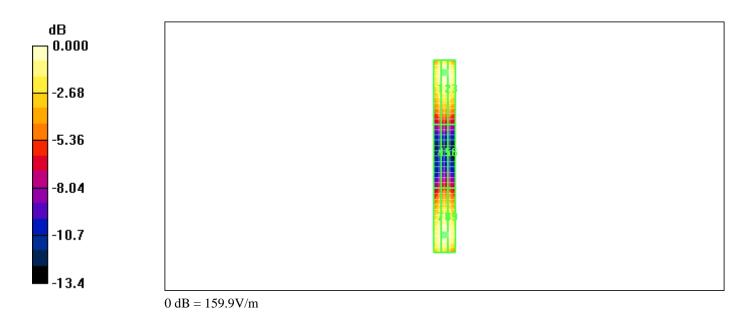
Reference Value = 115.7 V/m; Power Drift = 0.021 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
151.8 M4	159.9 M4	157.4 M4
Grid 4	Grid 5	Grid 6
80.7 M4	83.6 M4	82.6 M4
Grid 7	Grid 8	Grid 9
151.7 M4	154.5 M4	153.0 M4

Peak E-field in V/m

Testing Services™		nnex A to Hearing Aid Compatibility RF Emissions Test eport for the BlackBerry® Smartphone model		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	



Testing Services ^{**}	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 29 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 11:32:23 AM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_AM80%_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 72.4 V/m; Power Drift = 0.041 dB Maximum value of Total (measured) = 80.7 V/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 30 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011	eb. 28-Mar. 01, 2011 L6ARDP70U		

CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 81.1 V/m

Probe Modulation Factor = 1.00

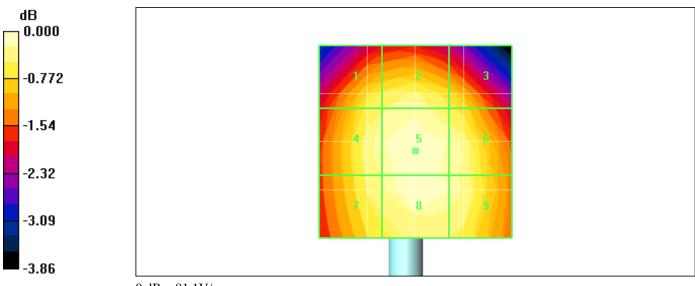
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 72.4 V/m; Power Drift = 0.041 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field	in V/m	
Grid 1	Grid 2	Grid 3
78.7 M4	80.0 M4	77.9 M4
Grid 4	Grid 5	Grid 6
79.8 M4	81.1 M4	80.3 M4
Grid 7	Grid 8	Grid 9
78.8 M4	80.3 M4	79.7 M4

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 31 (286)		
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH700 L6ARDP70U	- · ·





Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 32 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 11:14:50 AM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_CDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CDMA 800; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 43.0 V/m; Power Drift = -0.052 dB Maximum value of Total (measured) = 48.4 V/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 33 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 48.7 V/m

Probe Modulation Factor = 1.00

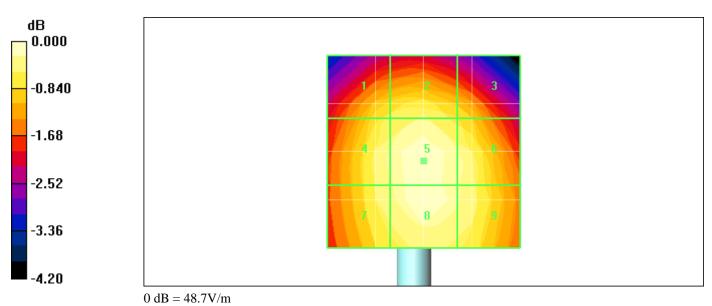
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 43.0 V/m; Power Drift = -0.052 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	n V/m	
Grid 1	Grid 2	Grid 3
46.0 M4	47.0 M4	45.7 M4
Grid 4	Grid 5	Grid 6
47.4 M4	48.7 M4	47.6 M4
Grid 7	Grid 8	Grid 9
47.0 M4	48.2 M4	47.3 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test			Page 34 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH700 L6ARDP70U	



Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 35 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 11:36:21 AM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_CW_CDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 44.6 V/m; Power Drift = -0.104 dB Maximum value of Total (measured) = 49.0 V/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 36 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 49.2 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

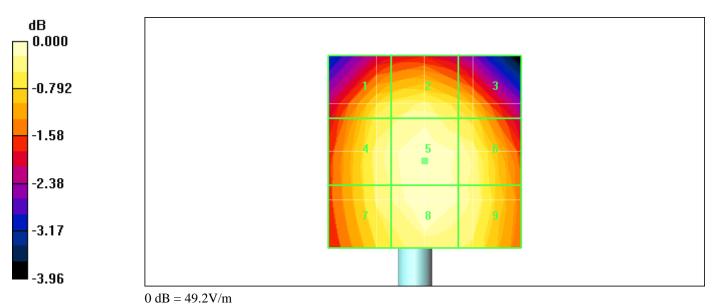
Reference Value = 44.6 V/m; Power Drift = -0.104 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

	V/m	
Grid 1	Grid 2	Grid 3
47.6 M4	48.5 M4	47.3 M4
Grid 4	Grid 5	Grid 6
48.3 M4	49.2 M4	48.7 M4
Grid 7	Grid 8	Grid 9

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Testing Services**		Aid Compatibility RF Emi Berry® Smartphone mode v		Page 37 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH700 L6ARDP700	



Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 38 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 11:41:20 AM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_AM80%_CDMA

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 28.3 V/m; Power Drift = -0.092 dB Maximum value of Total (measured) = 31.1 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		Page 39 (286)	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 31.3 V/m

Probe Modulation Factor = 1.00

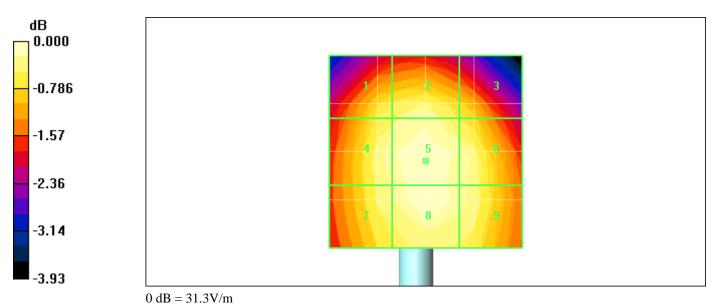
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 28.3 V/m; Power Drift = -0.092 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	n V/m	
Grid 1	Grid 2	Grid 3
30.3 M4	30.9 M4	29.9 M4
Grid 4	Grid 5	Grid 6
30.8 M4	31.3 M4	30.9 M4
Grid 7	Grid 8	Grid 9
30.4 M4	30.9 M4	30.7 M4

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 40 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70(L6ARDP70U	



Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 41 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/12/2011 2:35:41 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 128.4 V/m; Power Drift = -0.030 dB Maximum value of Total (measured) = 126.3 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		Page 42 (286)	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 127.8 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

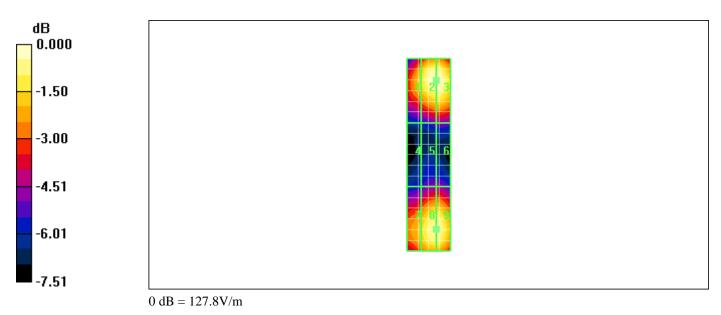
Reference Value = 128.4 V/m; Power Drift = -0.030 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in	V/m	
Grid 1	Grid 2	Grid 3
109.1 M3	127.8 M2	127.8 M2
Grid 4	Grid 5	Grid 6
68.3 M3	75.8 M3	75.8 M3
Grid 7	Grid 8	Grid 9
106.5 M3	123.0 M2	123.0 M2

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Testing Services ^{**}		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 43 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services ^{**}	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		Page 44 (286)	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 11:49:05 AM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 30.3 V/m; Power Drift = -0.038 dB Maximum value of Total (measured) = 29.7 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test		Page 45 (286)	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 30.2 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

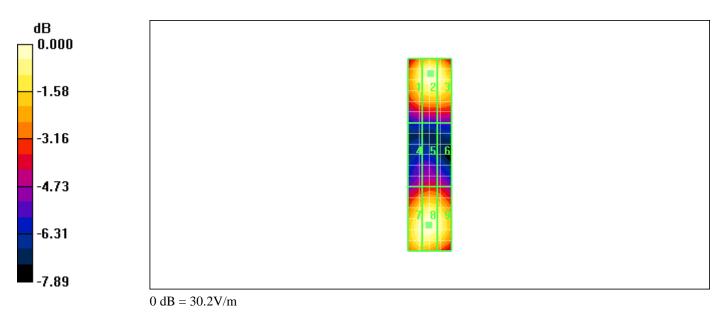
Reference Value = 30.3 V/m; Power Drift = -0.038 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
28.7 M4	30.2 M4	29.5 M4
Grid 4	Grid 5	Grid 6
19.0 M4	19.9 M4	19.4 M4
Grid 7	Grid 8	Grid 9

Testing Services ^{**}	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 46 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 47 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C Feb. 28-Mar. 01, 2011 L6ARDP70U L6ARDP70U		• •	

Date/Time: 1/19/2011 12:06:18 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_CW_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 86.9 V/m; Power Drift = 0.001 dB Maximum value of Total (measured) = 86.8 V/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 48 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C		CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 87.6 V/m

Probe Modulation Factor = 1.00

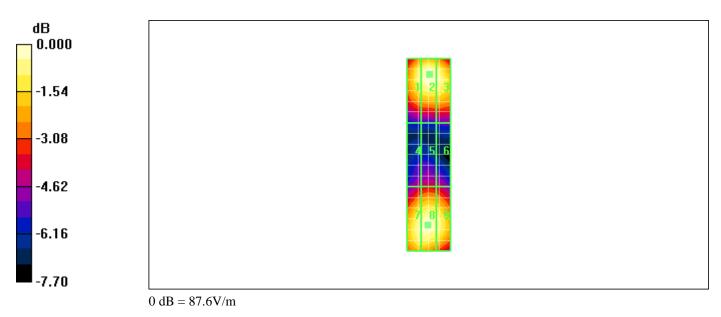
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 86.9 V/m; Power Drift = 0.001 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Peak E-field in	V/m	
Grid 1	Grid 2	Grid 3
83.8 M3	87.6 M3	85.3 M3
Grid 4	Grid 5	Grid 6
54.9 M4	56.9 M4	55.8 M4
Grid 7	Grid 8	Grid 9
84.5 M3	85.4 M3	83.1 M3

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 49 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 50 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C		CW	
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 12:14:44 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_AM80%_GSM

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 55.5 V/m; Power Drift = 0.016 dB Maximum value of Total (measured) = 44.8 V/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 51 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 45.2 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

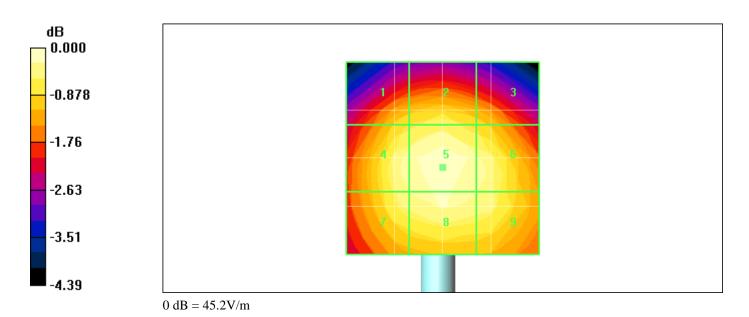
Reference Value = 55.5 V/m; Power Drift = 0.016 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	n V/m	
Grid 1	Grid 2	Grid 3
42.3 M4	43.1 M4	41.8 M4
Grid 4	Grid 5	Grid 6
44.4 M4	45.2 M4	44.3 M4
Grid 7	Grid 8	Grid 9
43.6 M4	44.4 M4	43.8 M4

Peak E-field in V/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 52 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



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Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 53 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 12:29:07 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_CDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 43.0 V/m; Power Drift = -0.010 dB Maximum value of Total (measured) = 41.9 V/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 54 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 42.2 V/m

Probe Modulation Factor = 1.00

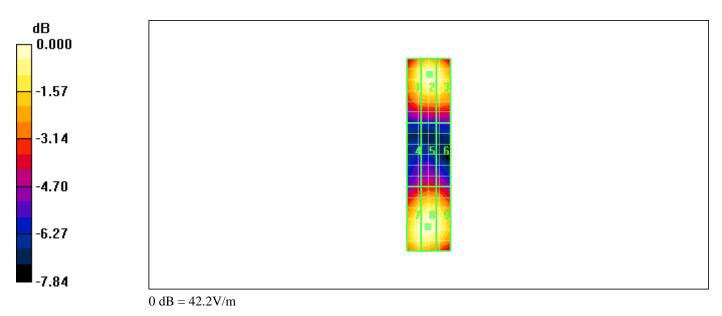
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 43.0 V/m; Power Drift = -0.010 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	n V/m	
Grid 1	Grid 2	Grid 3
39.9 M4	41.6 M4	40.7 M4
Grid 4	Grid 5	Grid 6
26.7 M4	27.8 M4	27.2 M4
Grid 7	Grid 8	Grid 9
41.5 M4	42.2 M4	41.0 M4

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 56 (286)		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	• •
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 1:40:16 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_CW_CDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 42.2 V/m; Power Drift = -0.002 dB Maximum value of Total (measured) = 41.8 V/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 57 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 42.1 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

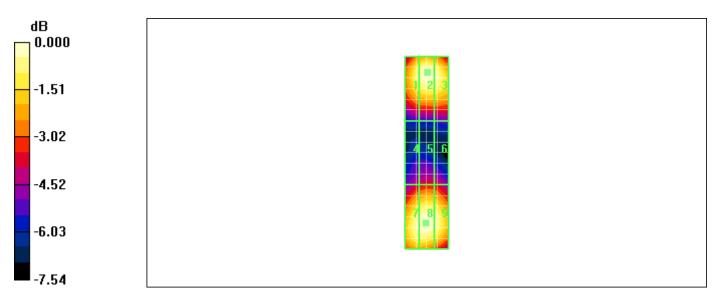
Reference Value = 42.2 V/m; Power Drift = -0.002 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	V/m	
Grid 1	Grid 2	Grid 3
40.1 M4	42.1 M4	41.2 M4
Grid 4	Grid 5	Grid 6
27.2 M4	28.2 M4	27.9 M4
Grid 7	Grid 8	Grid 9
41.1 M4	41.6 M4	40.8 M4

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Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			
Author Data	Dates of Test	Report No	FCC ID	•
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH700	CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \; dB = 42.1 V/m$

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 59 (286)		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 1:45:51 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_AM80%_CDMA

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 27.0 V/m; Power Drift = 0.044 dB Maximum value of Total (measured) = 21.7 V/m

Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 60 (286)
Dates of Test	Report No	FCC ID	
Jan. 12-19, 2011 Feb 28-Mar 01 2011	RTS-2605-1102-02A	L6ARDH70C	• •
	Report for the Black RDH71CW/RDP71UV Dates of Test	Annex A to Hearing Aid Compatibility RF Emis Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 Report No RTS-2605-1102-02A	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 Report No FCC ID L6ARDH70C

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 22.0 V/m

Probe Modulation Factor = 1.00

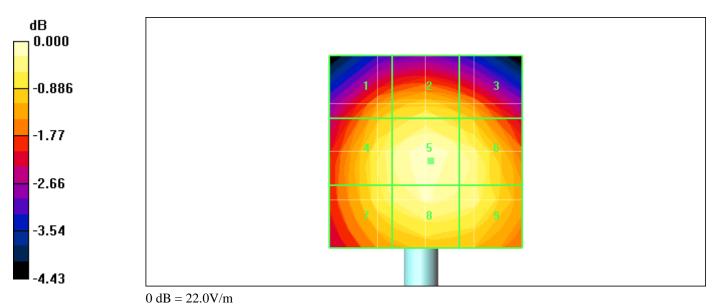
Device Reference Point: 0.000, 0.000, -6.30 mm

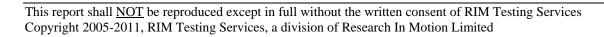
Reference Value = 27.0 V/m; Power Drift = 0.044 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field ir	n V/m	
Grid 1	Grid 2	Grid 3
20.4 M4	20.9 M4	20.3 M4
Grid 4	Grid 5	Grid 6
21.3 M4	22.0 M4	21.5 M4
Grid 7	Grid 8	Grid 9
21.0 M4	21.6 M4	21.3 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH700 L6ARDP700	





Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/12/2011 3:55:25 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.497 A/m; Power Drift = -0.014 dB Maximum value of Total (measured) = 0.466 A/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 63 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.467 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

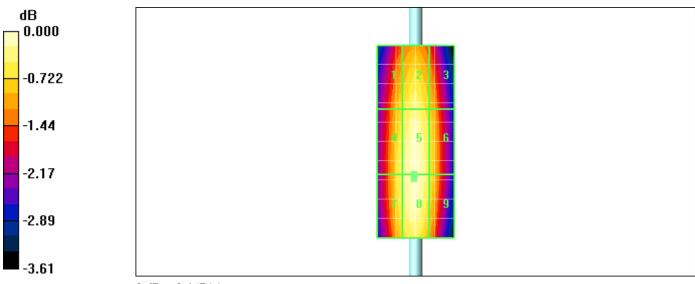
Reference Value = 0.497 A/m; Power Drift = -0.014 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.437 M4	0.450 M4	0.432 M4
Grid 4	Grid 5	Grid 6
0.450 M4	0.467 M4	0.444 M4
Grid 7	Grid 8	Grid 9
0.450 M4	0.467 M4	0.443 M4

Peak H-field in A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 64 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.467 A/m$

Testing Services ^{**}	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 65 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 3:04:45 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: GSM 850; Frequency: 835 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.174 A/m; Power Drift = -0.012 dB Maximum value of Total (measured) = 0.164 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 66 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.164 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

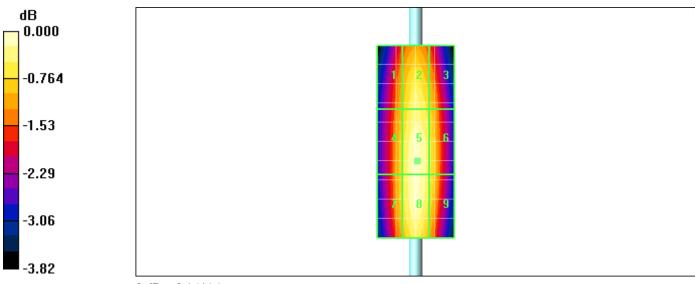
Reference Value = 0.174 A/m; Power Drift = -0.012 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m				
Grid 1	Grid 2	Grid 3		
0.148 M4	0.158 M4	0.152 M4		
Grid 4	Grid 5	Grid 6		
0.153 M4	0.164 M4	0.157 M4		
Grid 7	Grid 8	Grid 9		

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Testing Services™		Aid Compatibility RF Emis Berry® Smartphone model v		Page 67 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.164 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 68 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 3:29:53 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_CW_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.483 A/m; Power Drift = -0.026 dB Maximum value of Total (measured) = 0.458 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 69 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.458 A/m

Probe Modulation Factor = 1.00

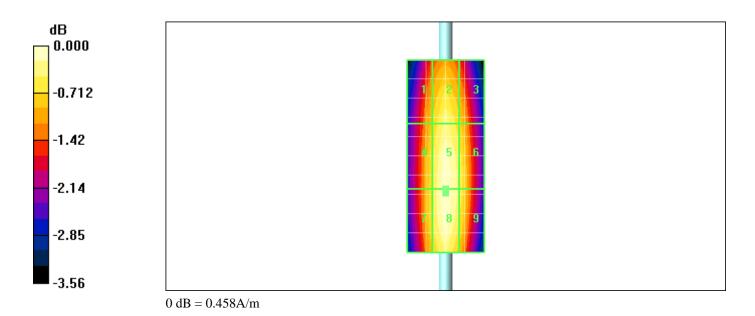
Device Reference Point: 0.000, 0.000, -6.30 mm

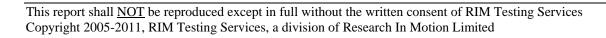
Reference Value = 0.483 A/m; Power Drift = -0.026 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.422 M4	0.441 M4	0.426 M4
Grid 4	Grid 5	Grid 6
0.433 M4	0.458 M4	0.441 M4
Grid 7	Grid 8	Grid 9

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone model v		Page 70 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70			CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W





Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 71 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 3:50:53 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_AM80%_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.306 A/m; Power Drift = -0.043 dB Maximum value of Total (measured) = 0.289 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 72 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.289 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

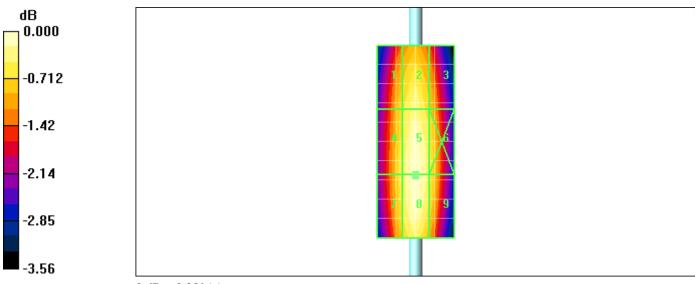
Reference Value = 0.306 A/m; Power Drift = -0.043 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3		
0.270 M4	0.280 M4	0.268 M4		
Grid 4	Grid 5	Grid 6		
0.276 M4	0.289 M4	0.277 M4		
Grid 7	Grid 8	Grid 9		
0.276 M4	0.289 M4	0.277 M4		

Peak H-field in A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 73 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.289 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 74 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 3:13:22 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_CDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CDMA 800; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.179 A/m; Power Drift = -0.011 dB Maximum value of Total (measured) = 0.169 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 75 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.170 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

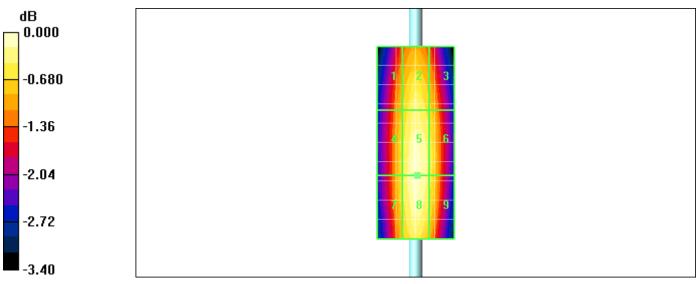
Reference Value = 0.179 A/m; Power Drift = -0.011 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.157 M4	0.164 M4	0.159 M4
Grid 4	Grid 5	Grid 6
0.161 M4	0.170 M4	0.164 M4
Grid 7	Grid 8	Grid 9
0.161 M4	0.170 M4	0.164 M4

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 76 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.170 \text{A/m}$

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Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 77 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	
	red. 20-War. 01, 2011		LUARDE /UU	vv

Date/Time: 1/19/2011 3:58:56 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_CW_CDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.181 A/m; Power Drift = -0.057 dB Maximum value of Total (measured) = 0.172 A/m

Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 78 (286)
Dates of Test Report No FCC ID			
Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	••
	Report for the Black RDH71CW/RDP71UW Dates of Test	Annex A to Hearing Aid Compatibility RF Emis Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 Report No RTS-2605-1102-02A	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 Report No FCC ID L6ARDH70C

CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.172 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

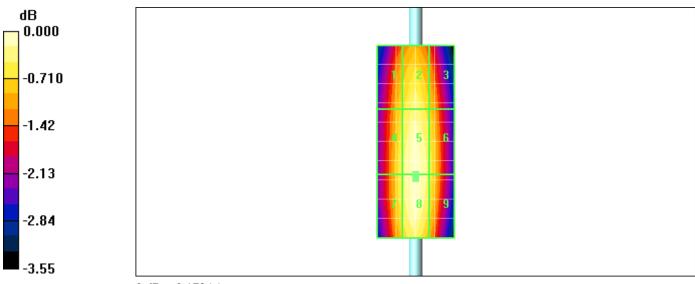
Reference Value = 0.181 A/m; Power Drift = -0.057 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A	A/m	
Grid 1	Grid 2	Grid 3
0.161 M4	0.166 M4	0.160 M4
Grid 4	Grid 5	Grid 6
0.165 M4	0.172 M4	0.165 M4
Grid 7	Grid 8	Grid 9
0.165 M4	0.172 M4	0.165 M4

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Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 79 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.172 \text{A/m}$

Testing Services ^{**}	Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 80 (286)		
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 3:54:05 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_AM80%_CDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.116 A/m; Power Drift = -0.014 dB Maximum value of Total (measured) = 0.110 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 81 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.110 A/m

Probe Modulation Factor = 1.00

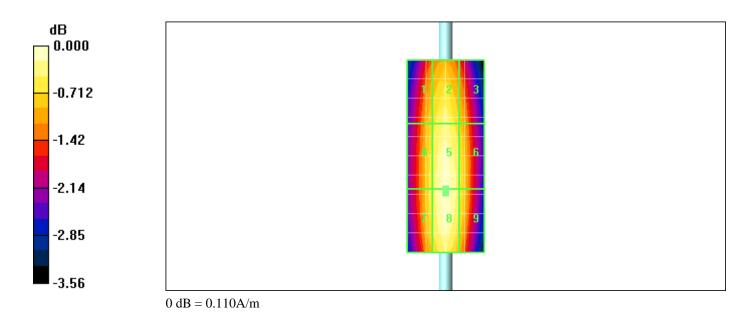
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.116 A/m; Power Drift = -0.014 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	n A/m	
Grid 1	Grid 2	Grid 3
0.103 M4	0.106 M4	0.102 M4
Grid 4	Grid 5	Grid 6
0.105 M4	0.110 M4	0.105 M4
Grid 7	Grid 8	Grid 9
0.105 M4	0.110 M4	0.105 M4

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone model v		Page 82 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 83 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/13/2011 2:49:30 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.478 A/m; Power Drift = 0.007 dB Maximum value of Total (measured) = 0.449 A/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 84 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.450 A/m

Probe Modulation Factor = 1.00

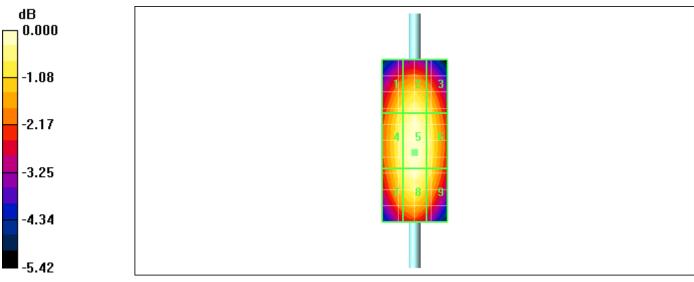
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.478 A/m; Power Drift = 0.007 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in	Peak H-field in A/m				
Grid 1	Grid 2	Grid 3			
0.416 M2	0.432 M2	0.413 M2			
Grid 4	Grid 5	Grid 6			
0.433 M2	0.450 M2	0.430 M2			
Grid 7	Grid 8	Grid 9			
0.425 M2	0.444 M2	0.422 M2			

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 85 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70			CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.450 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 86 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 2:23:57 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.131 A/m; Power Drift = -0.040 dB Maximum value of Total (measured) = 0.122 A/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 87 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011 L6ARDP70U			W

CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.122 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

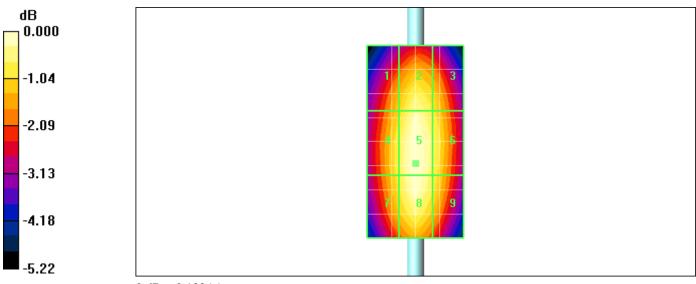
Reference Value = 0.131 A/m; Power Drift = -0.040 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in	Peak H-field in A/m				
Grid 1	Grid 2	Grid 3			
0.108 M4	0.117 M4	0.111 M4			
Grid 4	Grid 5	Grid 6			
0.113 M4	0.122 M4	0.116 M4			
Grid 7	Grid 8	Grid 9			
0.112 M4	0.121 M4	0.114 M4			

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Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 88 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.122 A/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 89 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 2:01:09 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_CW_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x5x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.325 A/m; Power Drift = -0.041 dB Maximum value of Total (measured) = 0.306 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 90 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011	Feb. 28-Mar. 01, 2011 L6ARDP70U		

CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x41x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.308 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

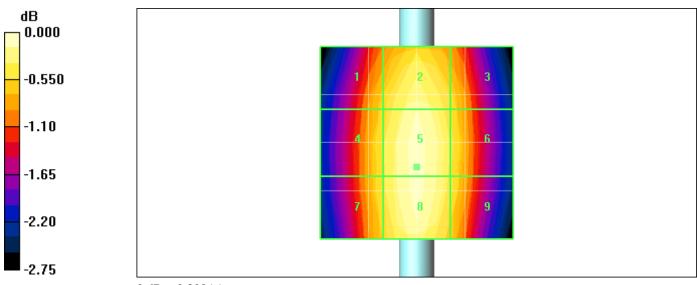
Reference Value = 0.325 A/m; Power Drift = -0.041 dB

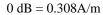
Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.293 M3	0.304 M3	0.296 M3
Grid 4	Grid 5	Grid 6
0.296 M3	0.308 M3	0.299 M3
Grid 7	Grid 8	Grid 9
0.296 M3	0.307 M3	0.298 M3

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 91 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	••





Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Page Report for the BlackBerry® Smartphone model 92 (286) Dates of Test Report No Jan. 12-19, 2011 RTS-2605-1102-02A		0	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 2:05:06 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_AM80%_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.211 A/m; Power Drift = -0.008 dB Maximum value of Total (measured) = 0.198 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test 93 Report for the BlackBerry® Smartphone model 93 RDH71CW/RDP71UW Pates of Test Dates of Test Report No		Page 93 (286)	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A		
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.199 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

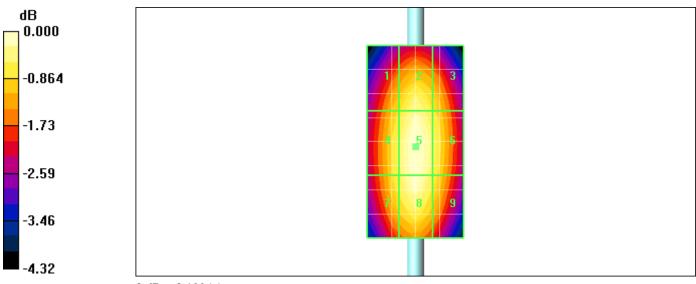
Reference Value = 0.211 A/m; Power Drift = -0.008 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.182 M4	0.191 M3	0.185 M4
Grid 4	Grid 5	Grid 6
Ond 4	Ond 5	Ond 0
0.189 M4	0.199 M3	0.190 M3
Grid 7	Grid 8	Grid 9
0.187 M4	0.196 M3	0.187 M4

Peak H-field in A/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 94 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	CW
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.199 A/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Page Report for the BlackBerry® Smartphone model 95 (286) RDH71CW/RDP71UW Dates of Test FCC ID Dates of Test RTS-2605-1102-02A FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW		U	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 2:40:36 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_CDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.109 A/m; Power Drift = 0.002 dB Maximum value of Total (measured) = 0.102 A/m

Testing Services™	RDH71CW/RDP71UW Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A FCC ID		Page 96 (286)	
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A		
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.103 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

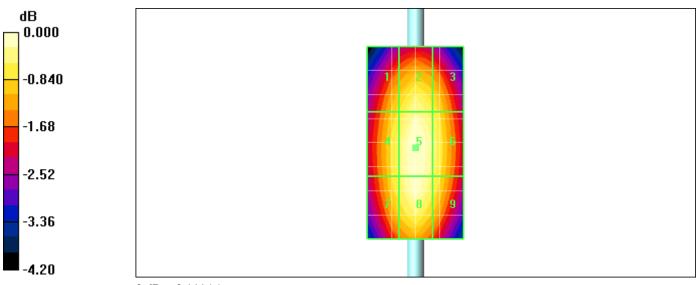
Reference Value = 0.109 A/m; Power Drift = 0.002 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.093 M4	0.101 M4	0.097 M4
Grid 4	Grid 5	Grid 6
0.100 M4	0.103 M4	0.102 M4
Grid 7	Grid 8	Grid 9
0.098 M4	0.102 M4	0.097 M4

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Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 97 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.111 A/m$

Testing Services™	,			
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A		
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 2:51:37 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_CW_CDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.117 A/m; Power Drift = 0.014 dB Maximum value of Total (measured) = 0.111 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.111 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.117 A/m; Power Drift = 0.014 dB

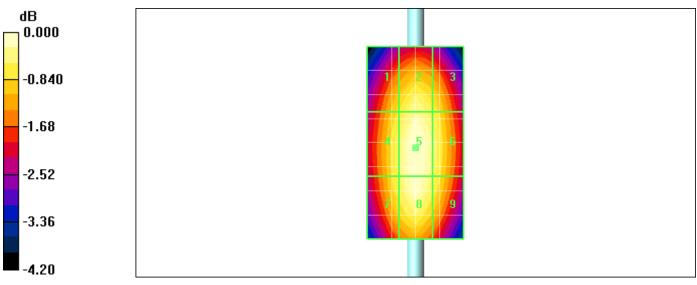
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.102 M4	0.107 M4	0.104 M4
Grid 4	Grid 5	Grid 6
0.106 M4	0.111 M4	0.107 M4
Grid 7	Grid 8	Grid 9
0.105 M4	0.110 M4	0.106 M4

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Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 100 (286)		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.111 A/m$

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 101 (286)		
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 2:54:42 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_AM80%_CDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.084 A/m; Power Drift = 0.004 dB Maximum value of Total (measured) = 0.080 A/m

Testing Services™	Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 102 (286)		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.080 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

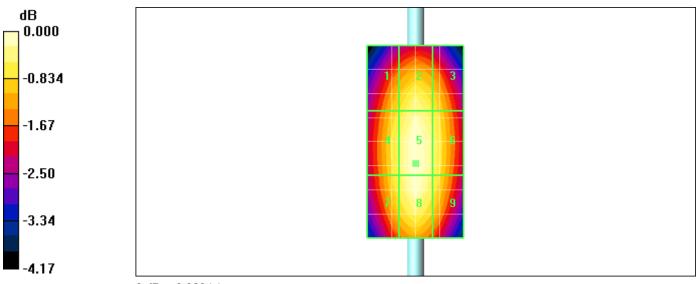
Reference Value = 0.084 A/m; Power Drift = 0.004 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.074 M4	0.077 M4	0.075 M4
	0-:15	Cridic
Grid 4	Grid 5	Grid 6
0.076 M4	0.080 M4	0.077 M4
Grid 7	Grid 8	Grid 9
0.076 M4	0.079 M4	0.076 M4
5.070 1014		

Peak H-field in A/m

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.080 A/m$

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 104 (286)		
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 2/28/2011 12:29:19 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_validation_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz);

Frequency: 835 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

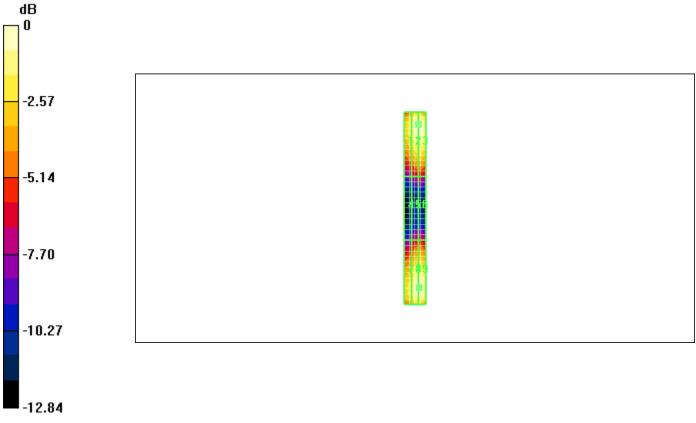
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 121.9 V/m; Power Drift = -0.07 dB Maximum value of Total (measured) = 164.8 V/m

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Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	



 $0 \ dB = 164.8 V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 106 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	

Date/Time: 2/28/2011 1:07:46 PM

Test Laboratory: RIM Testing Services

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: WCDMA FDD V; Communication System Band: Exported from older format (data unavailable - please correct).; Frequency: 835 MHz;Communication System PAR: 0 dB Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 56.944 V/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

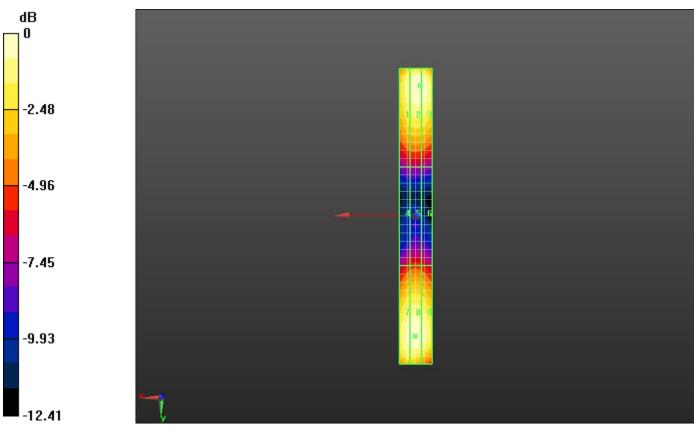
Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 107 (286)		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 42.995 V/m; Power Drift = 0.01 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V	//m	
Grid 1	Grid 2	Grid 3
53.505 M4	56.944 M4	56.718 M4
Grid 4	Grid 5	Grid 6
30.372 M4	31.039 M4	30.245 M4
Grid 7	Grid 8	Grid 9
54.971 M4	56.115 M4	54.501 M4

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 56.940 V/m$

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Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	

Date/Time: 2/28/2011 12:43:40 PM

Test Laboratory: RIM Testing Services

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

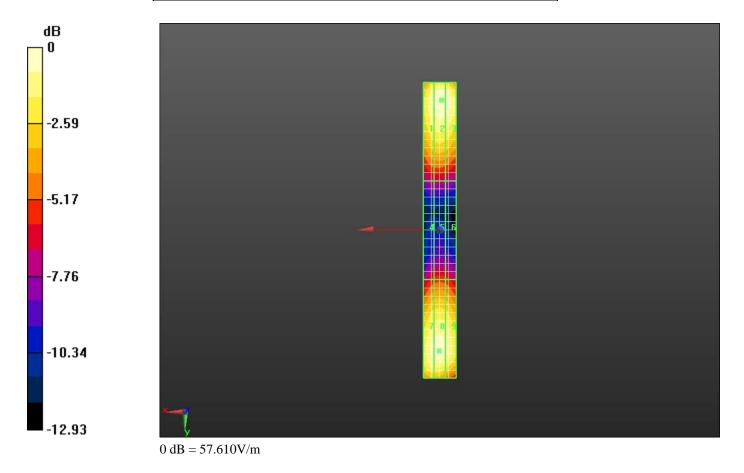
- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 57.608 V/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 42.622 V/m; Power Drift = -0.06 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 110 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70CW L6ARDP70UW	

Grid 1	Grid 2	Grid 3
54.388 M4	57.608 M4	56.620 M4
Grid 4	Grid 5	Grid 6
30.355 M4	30.943 M4	30.261 M4
Grid 7	Grid 8	Grid 9
54.334 M4	55.102 M4	53.476 M4



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Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV Feb. 28-Mar. 01, 2011 L6ARDP70UV L6ARDP70UV			

Date/Time: 2/28/2011 12:54:03 PM

Test Laboratory: RIM Testing Services

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Communication System Band: D835 (835.0 MHz); Frequency: 835 MHz;Communication System PAR: 0 dB Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

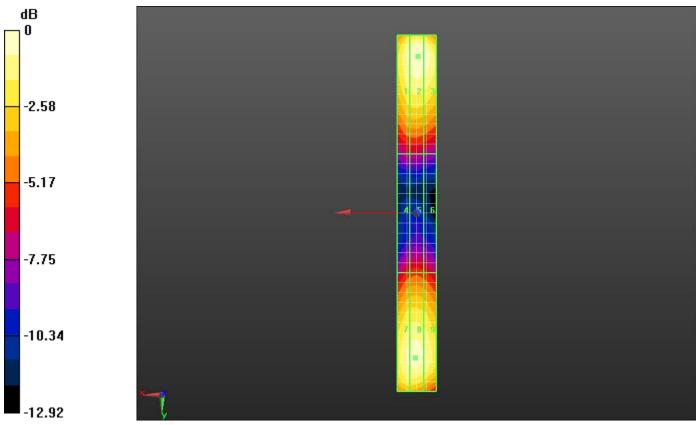
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 37.106 V/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 26.469 V/m; Power Drift = 0.17 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Service	Report for the Black	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
35.158 M4	37.106 M4	36.227 M4
Grid 4	Grid 5	Grid 6
19.445 M4	19.878 M4	19.259 M4
Grid 7	Grid 8	Grid 9
34.812 M4	35.203 M4	34.158 M4

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 113 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 37.110 V/m$

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 114 (286)
Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C Feb. 28-Mar. 01, 2011 L6ARDP70UV			

Date/Time: 2/28/2011 3:08:59 PM

Test Laboratory: RIM Testing Services

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0

MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

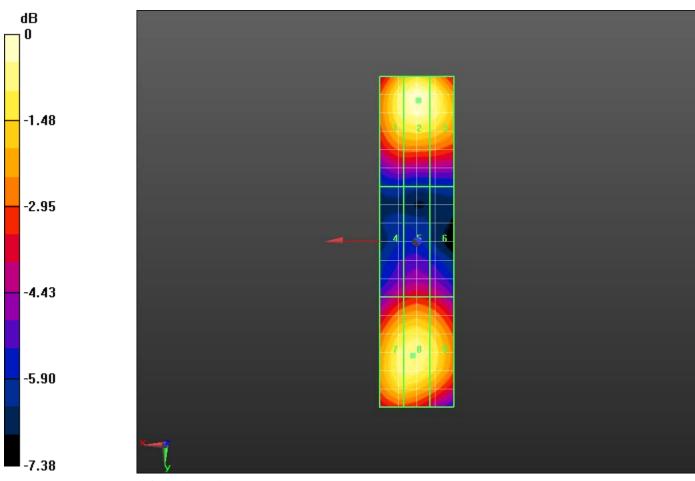
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 132.7 V/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 120.8 V/m; Power Drift = -0.02 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Grid 1	Grid 2	Grid 3
126.7 M2	132.7 M2	128.5 M2
Grid 4	Grid 5	Grid 6
86.778 M3	89.711 M3	87.123 M3
Grid 7	Grid 8	Grid 9
123.6 M2	124.4 M2	119.5 M2

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Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 132.7 \ V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 117 (286)
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-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 2/28/2011 2:07:15 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_UMTS_band_II_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: WCDMA FDD II; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency: 1880

MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 38.483 V/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 118 (286)
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Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

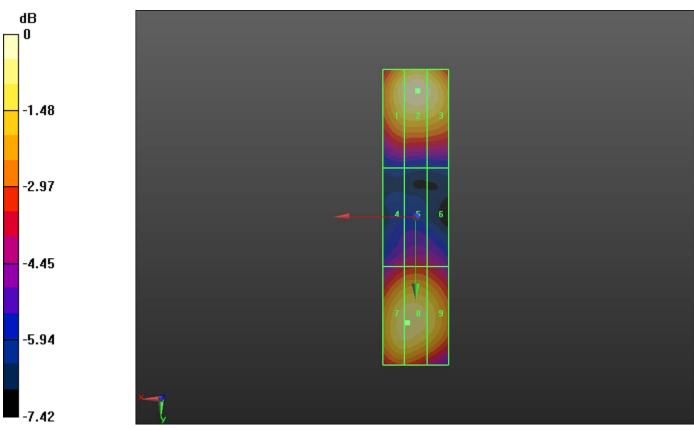
Reference Value = 35.028 V/m; Power Drift = 0.10 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V	/m	
Grid 1	Grid 2	Grid 3
36.706 M4	38.483 M4	37.337 M4
Grid 4	Grid 5	Grid 6
24.878 M4	25.643 M4	25.076 M4
Grid 7	Grid 8	Grid 9
35.871 M4	35.988 M4	34.479 M4

Peak E-field in V/m

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	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 38.480 V/m$

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Date/Time: 2/28/2011 2:16:59 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_PMF_CW1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0

MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
 - o Modulation Compensation: Not calibrated
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 38.861 V/m; Power Drift = 0.02 dB Maximum value of Total (measured) = 42.392 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 121 (286)
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	Feb. 28-Mar. 01, 2011	K15-2005-1102-02A	L6ARDP70U	••

Date/Time: 2/28/2011 2:16:59 PM

Test Laboratory: RIM Testing Services

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0

MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

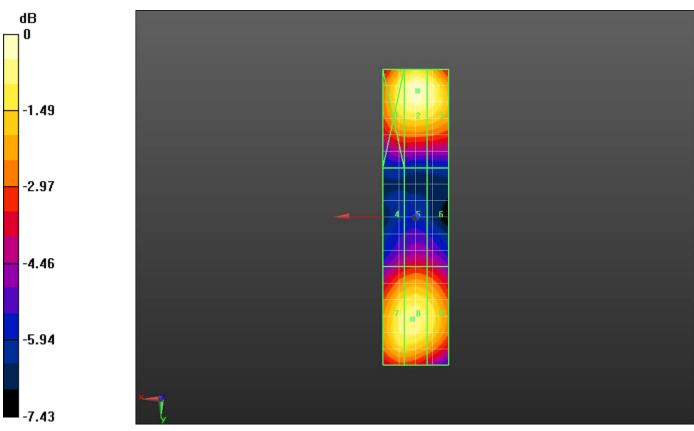
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 43.024 V/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 38.861 V/m; Power Drift = 0.02 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH700	CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
40.897 M4	43.024 M4	41.671 M4
Grid 4	Grid 5	Grid 6
27.919 M4	28.886 M4	28.274 M4
Grid 7	Grid 8	Grid 9
39.759 M4	40.082 M4	38.641 M4

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 43.020 V/m$

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Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011 L6ARDP70UW			W

Date/Time: 2/28/2011 2:21:55 PM

Test Laboratory: RIM Testing Services

DUT: HAC Dipole AM 80%_1880 MHz; Type: CD1880V3

Communication System: AM 80%; Communication System Band: D1900 (1900.0

MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

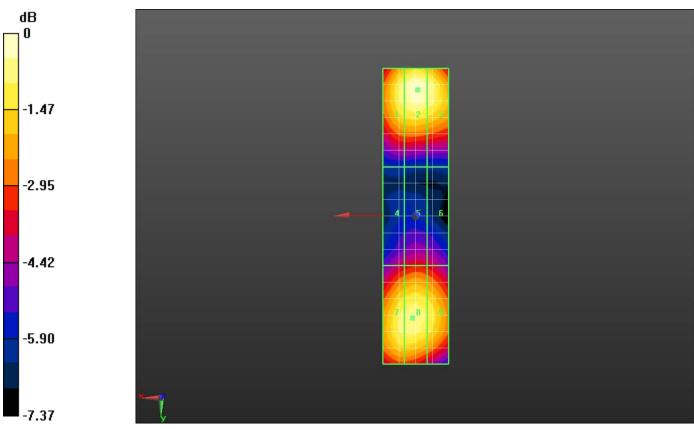
Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 27.543 V/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 25.024 V/m; Power Drift = -0.0069 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 125 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
26.151 M4	27.543 M4	26.639 M4
Grid 4	Grid 5	Grid 6
17.904 M4	18.574 M4	18.189 M4
Grid 7	Grid 8	Grid 9
25.506 M4	25.701 M4	24.770 M4

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 126 (286)
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Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \; dB = 27.540 V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 127 (286)
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Date/Time: 2/28/2011 3:55:23 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz);

Frequency: 835 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.478 A/m Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

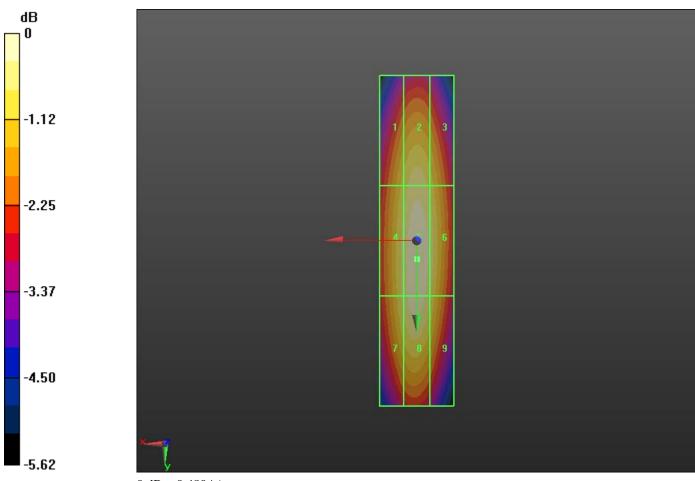
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 128 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 0.507 A/m; Power Drift = 0.02 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.432 M4	0.453 M4	0.435 M4
Grid 4	Grid 5	Grid 6
0.452 M4	0.478 M4	0.456 M4
Grid 7	Grid 8	Grid 9
0.450 M4	0.472 M4	0.444 M4

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 129 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.480 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 130 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 2/28/2011 3:32:16 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_UMTS_band V_835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: WCDMA FDD V; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency: 835

MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement

distance from the probe sensor center to CD835 Dipole =

10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.168 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

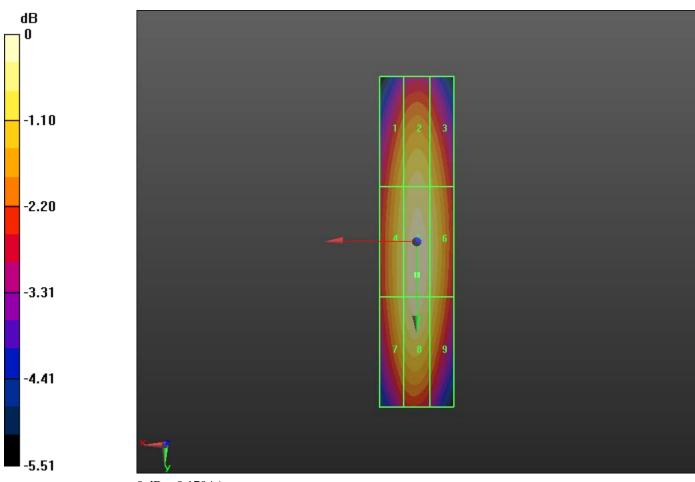
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 131 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 0.178 A/m; Power Drift = 0.23 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.153 M4	0.160 M4	0.154 M4
Grid 4	Grid 5	Grid 6
0.160 M4	0.168 M4	0.161 M4
Grid 7	Grid 8	Grid 9
0.159 M4	0.166 M4	0.157 M4

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 132 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.170 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 133 (286)
Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 2/28/2011 3:41:08 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_CW835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: CW; Communication System Band: D835 (835.0 MHz);

Frequency: 835 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole =

10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.166 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

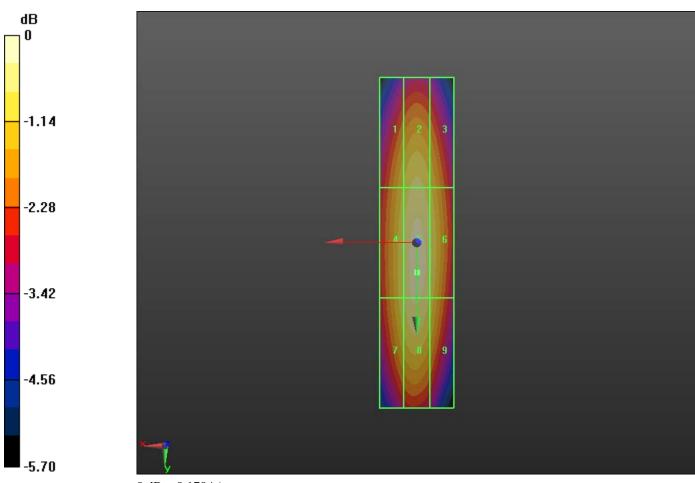
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 134 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	• •

Reference Value = 0.177 A/m; Power Drift = -0.10 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.151 M4	0.158 M4	0.151 M4
Grid 4	Grid 5	Grid 6
0.157 M4	0.166 M4	0.159 M4
Grid 7	Grid 8	Grid 9
0.156 M4	0.164 M4	0.155 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 135 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.170 A/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 136 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			W
-	Feb. 28-Mar. 01, 2011 L6ARDP70U			W

Date/Time: 2/28/2011 3:45:30 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_AM80%835 MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%; Communication System Band: D835 (835.0

MHz); Frequency: 835 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.106 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 137 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

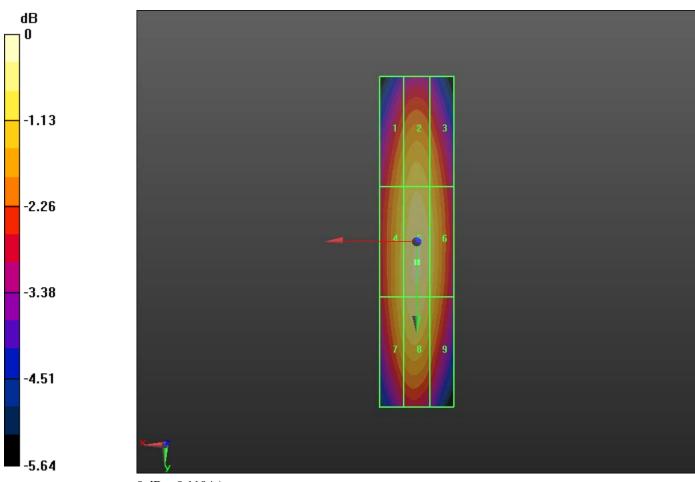
Reference Value = 0.113 A/m; Power Drift = 0.0097 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.096 M4	0.100 M4	0.096 M4
Grid 4	Grid 5	Grid 6
0.100 M4	0.106 M4	0.101 M4
Grid 7	Grid 8	Grid 9
0.100 M4	0.104 M4	0.098 M4

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 138 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.110 A/m

Testing Services ^{**}	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 139 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C Feb. 28-Mar. 01, 2011 L6ARDP70U			

Date/Time: 2/28/2011 3:21:34 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0

MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.455 A/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 140 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

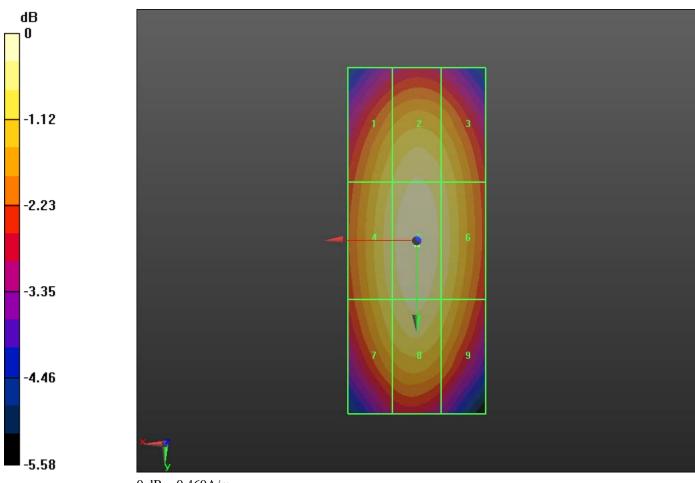
Reference Value = 0.483 A/m; Power Drift = -0.0087 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.424 M2	0.443 M2	0.428 M2
Grid 4	Grid 5	Grid 6
0.437 M2	0.455 M2	0.438 M2
Grid 7	Grid 8	Grid 9
0.428 M2	0.446 M2	0.424 M2

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Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 141 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.460 A/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 142 (286)
Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 2/28/2011 2:57:08 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_UMTS_band II_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: WCDMA FDD II; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency: 1880

MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement

distance from the probe sensor center to CD1880 Dipole =

10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.138 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 143 (286)
Author Data	Dates of Test	Dates of Test Report No FCC ID		
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

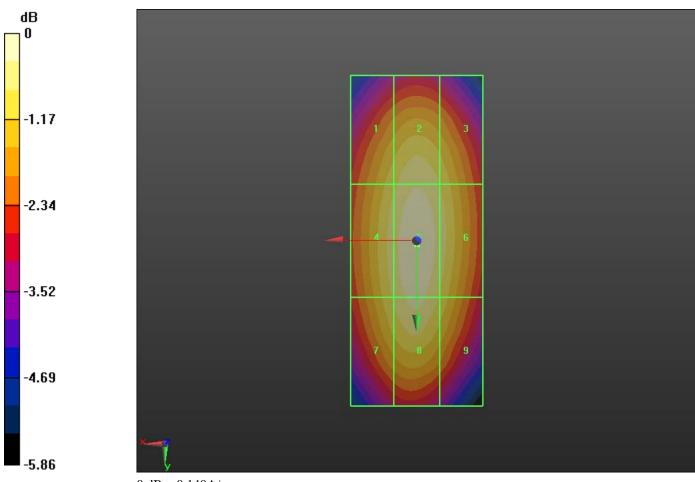
Reference Value = 0.147 A/m; Power Drift = 0.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A	A/m	
Grid 1	Grid 2	Grid 3
0.127 M4	0.134 M4	0.128 M4
Grid 4	Grid 5	Grid 6
0.132 M4	0.138 M4	0.132 M4
Grid 7	Grid 8	Grid 9
0.129 M4	0.136 M4	0.127 M4

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Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 144 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
-	Feb. 28-Mar. 01, 2011		L6ARDP70UW	



0 dB = 0.140 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 145 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	

Date/Time: 2/28/2011 2:40:44 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_CW1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0

MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: TCoil Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.155 A/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

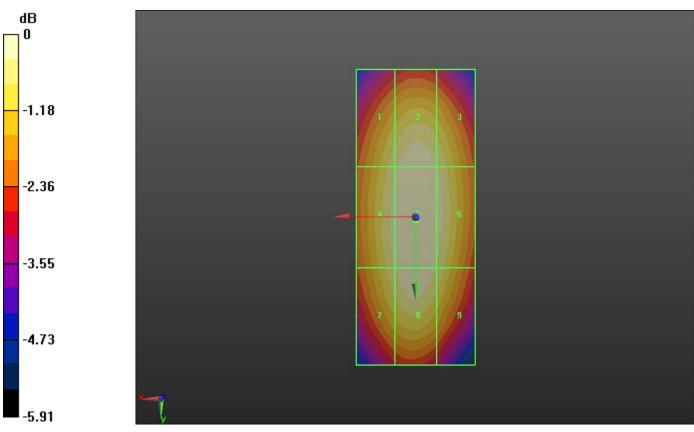
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 146 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 0.163 A/m; Power Drift = 0.06 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.142 M4	0.149 M4	0.144 M4
Grid 4	Grid 5	Grid 6
0.147 M4	0.155 M4	0.148 M4
Grid 7	Grid 8	Grid 9
0.143 M4	0.151 M4	0.143 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 147 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \; dB = 0.150 A/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 148 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 2/28/2011 2:44:44 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_PMF_AM80%1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: AM 80%; Communication System Band: D1900 (1900.0

MHz); Frequency: 1880 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: TCoil Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.099 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

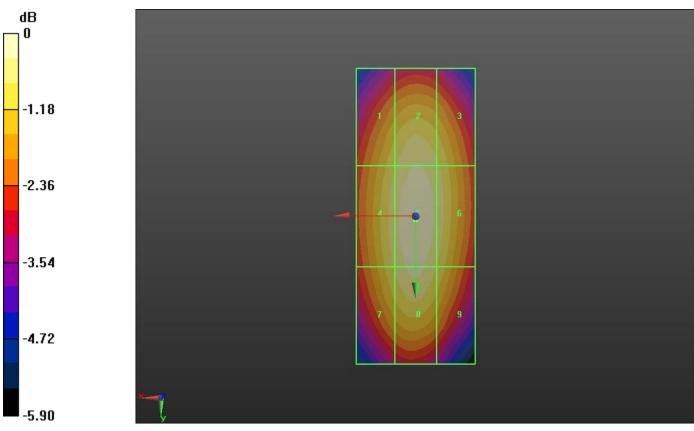
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 149 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 0.106 A/m; Power Drift = 0.0091 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

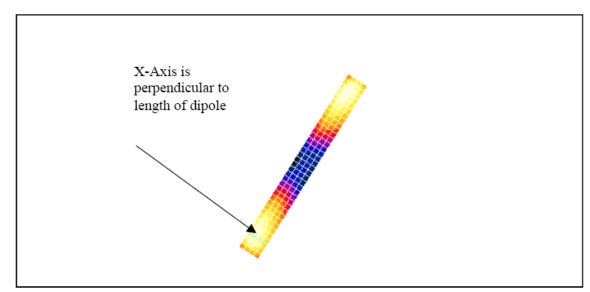
Peak H-field in A	A/m	
Grid 1	Grid 2	Grid 3
0.091 M4	0.096 M4	0.092 M4
Grid 4	Grid 5	Grid 6
0.094 M4	0.099 M4	0.095 M4
Grid 7	Grid 8	Grid 9
0.092 M4	0.097 M4	0.091 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 150 (286)
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Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 0.100 A/m$

Testing Services™	DocumentPageAnnex A to Hearing Aid Compatibility RF Emissions Test151 (2Report for the BlackBerry® Smartphone model151 (2RDH71CW/RDP71UW151 (2			Page 151 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	••



The green line in this figure shows the axis along which the points lie.

Comparison of 5mm and 2mm step sizes

An additional set of measurements was taken: dipole validations were performed using 5mm and 2mm step sizes. The delta between the two readings is insignificant for both field types (< 0.4% for E and 0% for H), demonstrating that 5mm is sufficient. The plots follow.

Testing Services ^{**}	Annex A to Hearing Aid Compatibility RF Emissions Test			Page 152 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 14/07/2005 11:35:24 AM

Page 1 of 2

Date/Time: 14/07/2005 11:35:24 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of Total (measured) = 134.8 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of Total field (slot averaged) = 131.0 V/m Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

Grid 1			Grid 1	Grid 2	Grid 3
123.2	138.1	138.4	123.2	138.1	138.4
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
80.9	92.3	92.2	80.9	92.3	92.2
		Grid 9			Grid 9
119.8	131.0	130.7	119.8	131.0	130.7

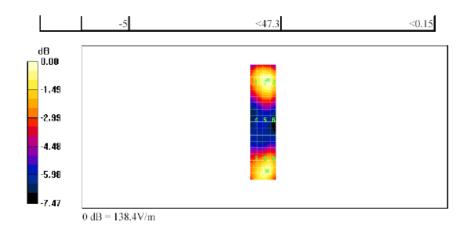
Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

 $file: // C: Program \% 20 Files \ DASY4 \ Print_Templates \ Dipole \% 20 \ Validation \% 201880\% 20... 14/07/2005$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 153 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 14/07/2005 11:35:24 AM

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file://C:\Program%20Files\DASY4\Print_Templates\Dipole%20Validation%201880%20... 14/07/2005

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Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 14/07/2005 11:44:51 AM

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Date/Time: 14/07/2005 11:44:51 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_2mm step_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³ Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn472; Calibrated: 03/01/2005

- Phantom: HAC Test Arch; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1): Measurement grid: dx=2mm, dy=2mm

Maximum value of Total (measured) = 138.0 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm Maximum value of Total field (slot averaged) = 131.2 V/m Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.1	138.6	138.6	123.1	138.6	138.6
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
81.4	92.1	91.6	81.4	92.1	91.6
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
121.3	131.2	131.0	121.3	131.2	131.0

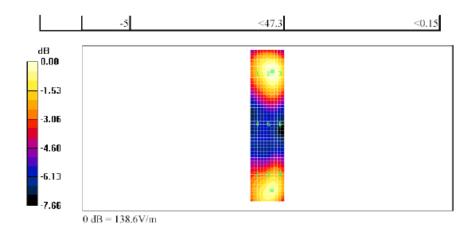
Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

 $file: // C: Program \% 20 Files \ DASY4 \ Print_Templates \ Dipole \% 20 \ Validation \% 201880\% 20... 14/07/2005$

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 155 (286)
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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV Feb. 28-Mar. 01, 2011 L6ARDP70UV L6ARDP70UV			

Date/Time: 14/07/2005 11:44:51 AM

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Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Date/Time: 14/07/2005 12:43:02 PM

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Date/Time: 14/07/2005 12:43:02 PM

Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_5 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of Total field (slot averaged) = 0.406 A/m Hearing Aid Near-Field Category: M2 (AWF 0 dB)

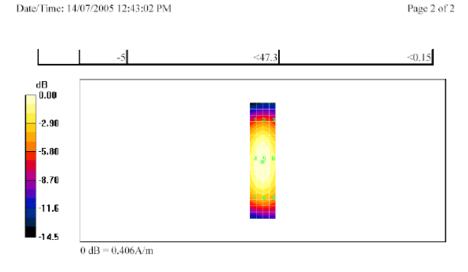
H in A/m (Time averaged) H in A/m (Slot averaged)

	Grid 3 0.344		Grid 2 0.359	
	0.544 Grid 6		Grid 5	
	0.389		0.406	
	Grid 9 0.363		Grid 8 0.378	

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

file://C:\Program%20Files\DASY4\Print_Templates\HAC_H_Dipole_CW%201880_5%... 14/07/2005

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	Annex A to Hearing Report for the Black RDH71CW/RDP71UV Dates of Test	Annex A to Hearing Aid Compatibility RF En Report for the BlackBerry® Smartphone mod RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 Report No RTS-2605-1102-02A	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Jan. 12-19, 2011 RTS-2605-1102-02A



file://C:\Program%20Files\DASY4\Print_Templates\HAC_H_Dipole_CW%201880_5%... 14/07/2005

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test			Page 158 (286)
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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV			W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 14/07/2005 12:53:40 PM

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Date/Time: 14/07/2005 12:53:40 PM

Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_2 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³ Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 10/12/2004

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn472; Calibrated: 03/01/2005

- Phantom: HAC Test Arch; Type: SD HAC P01 BA;

- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):

Measurement grid: dx=2mm, dy=2mm

Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm Maximum value of Total field (slot averaged) = 0.406 A/m Hearing Aid Near-Field Category: M2 (AWF 0 dB)

H in A/m (Time averaged) H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
0.347	0.361	0.348	0.347	0.361	0.348
Grid 4	Grid 5	Grid 6		Grid 5	
0.394	0.406	0.391	0.394	0.406	0.391
Grid 7	Grid 8	Grid 9		Grid 8	
0.367	0.380	0.365	0.367	0.380	0.365

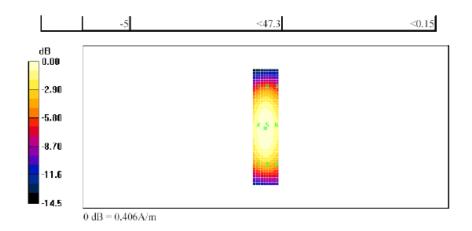
Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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Testing Services™	Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 159 (286)				
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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C Feb. 28-Mar. 01, 2011 L6ARDP70U					

Date/Time: 14/07/2005 12:53:40 PM

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C				
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A.3 RF emissions plots

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C			CW	
	Feb. 28-Mar. 01, 2011 L6ARDP70UV			W	

Date/Time: 1/19/2011 5:04:29 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_low_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 87.7 V/m; Power Drift = -0.180 dB Maximum value of Total (measured) = 67.2 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 195.4 V/m

Probe Modulation Factor = 2.90

Device Reference Point: 0.000, 0.000, -6.30 mm

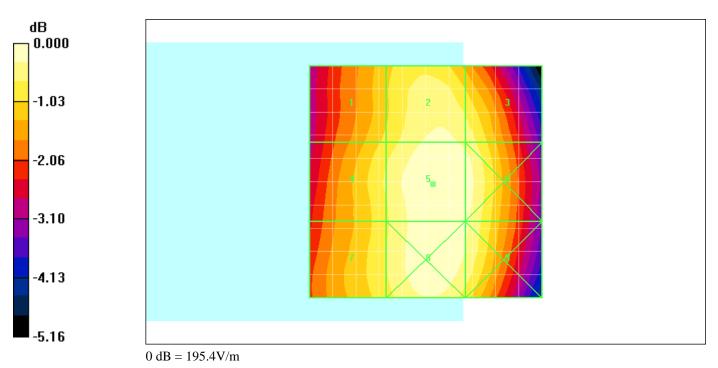
Reference Value = 87.7 V/m; Power Drift = -0.180 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
176.0 M3	190.1 M3	186.0 M3
Grid 4	Grid 5	Grid 6
181.7 M3	195.4 M3	191.6 M3
Grid 7	Grid 8	Grid 9
Ond /	Grid 8	Grid 9

Peak E-field in V/m

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	Feb. 28-Mar. 01, 2011	W				



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Date/Time: 1/19/2011 5:11:37 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_mid_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 91.2 V/m; Power Drift = 0.212 dB Maximum value of Total (measured) = 72.8 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 211.5 V/m

Probe Modulation Factor = 2.90

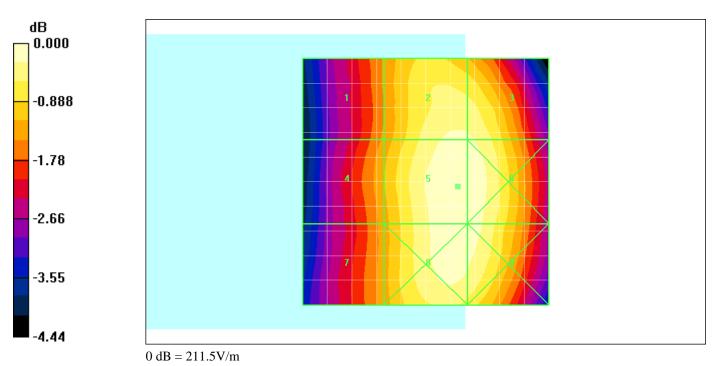
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 91.2 V/m; Power Drift = 0.212 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in	V/m	
Grid 1	Grid 2	Grid 3
180.3 M3	206.1 M3	205.7 M3
Grid 4	Grid 5	Grid 6
184.4 M3	211.5 M3	211.2 M3
Grid 7	Grid 8	Grid 9
182.1 M3	209.9 M3	209.0 M3

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	Feb. 28-Mar. 01, 2011			

Date/Time: 1/19/2011 5:18:04 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_high_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 96.9 V/m; Power Drift = -0.021 dB Maximum value of Total (measured) = 76.7 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 223.9 V/m

Probe Modulation Factor = 2.90

Device Reference Point: 0.000, 0.000, -6.30 mm

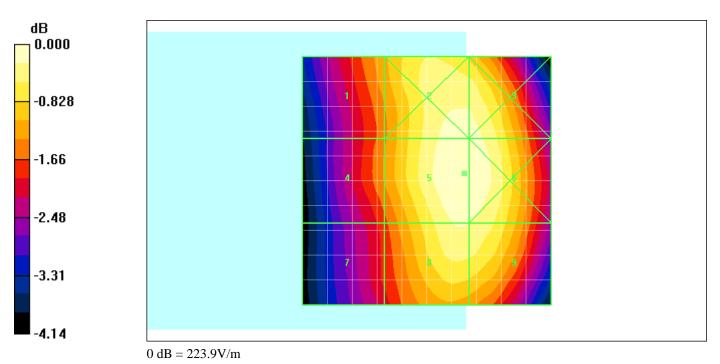
Reference Value = 96.9 V/m; Power Drift = -0.021 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
196.0 M3	221.1 M3	220.8 M3
Grid 4	Grid 5	Grid 6
192.0 M3	223.9 M3	223.7 M3
Grid 7	Grid 8	Grid 9
183.4 M3	217.6 M3	217.0 M3

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW					
	Feb. 28-Mar. 01, 2011 L6ARDP70UW					



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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			W
	Feb. 28-Mar. 01, 2011 L6ARDP70UW			W

Date/Time: 1/19/2011 5:23:08 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_high_chan_Telecoil_Center

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 96.4 V/m; Power Drift = -0.071 dB Maximum value of Total (measured) = 77.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 222.4 V/m

Probe Modulation Factor = 2.90

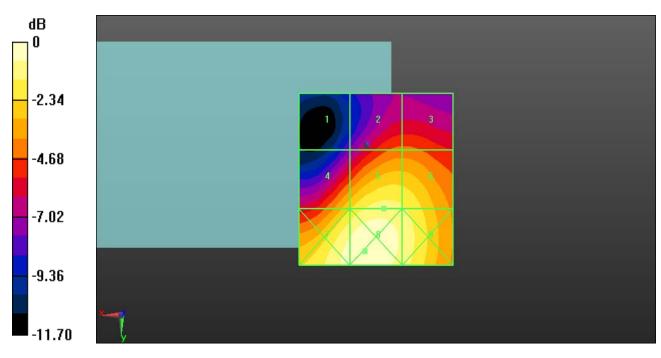
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 96.4 V/m; Power Drift = -0.071 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in	V/m	
Grid 1	Grid 2	Grid 3
183.5 M3	217.8 M3	218.5 M3
Grid 4	Grid 5	Grid 6
181.0 M3	222.4 M3	223.7 M3
Grid 7	Grid 8	Grid 9
174.8 M3	218.2 M3	219.9 M3

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⁰ dB = 223.7V/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 173 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
-	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 5:28:49 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_low_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 13.6 V/m; Power Drift = 0.040 dB Maximum value of Total (measured) = 24.6 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 53.8 V/m

Probe Modulation Factor = 2.90

Device Reference Point: 0.000, 0.000, -6.30 mm

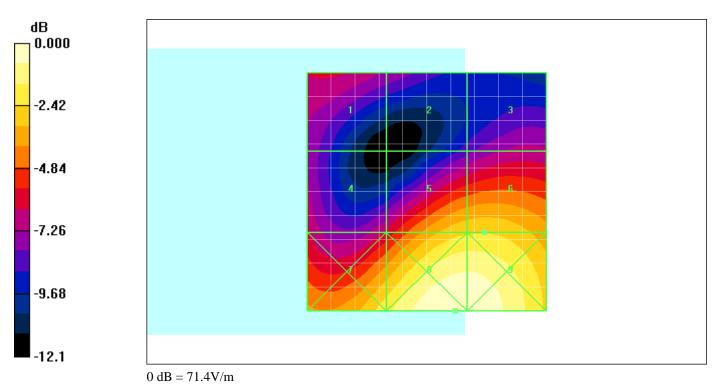
Reference Value = 13.6 V/m; Power Drift = 0.040 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
34.7 M4	30.8 M4	32.2 M4
Grid 4	Grid 5	Grid 6
34.7 M4	53.3 M3	53.8 M3
Grid 7	Grid 8	Grid 9
57.6 M3	71.4 M3	70.9 M3

Peak E-field in V/m

Testing Services™		Aid Compatibility RF Emis Berry® Smartphone model v		Page 175 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
•	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services™		Aid Compatibility RF Emis Berry® Smartphone mode v		Page 176 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 5:34:53 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_mid_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 15.2 V/m; Power Drift = -0.099 dB Maximum value of Total (measured) = 23.7 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 53.3 V/m

Probe Modulation Factor = 2.90

Device Reference Point: 0.000, 0.000, -6.30 mm

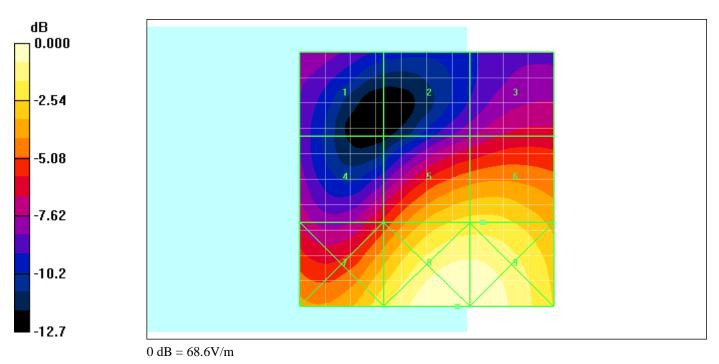
Reference Value = 15.2 V/m; Power Drift = -0.099 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in	n V/m	
Grid 1	Grid 2	Grid 3
28.3 M4	28.5 M4	32.9 M4
Grid 4	Grid 5	Grid 6
35.7 M4	53.1 M3	53.3 M3
Grid 7	Grid 8	Grid 9
55.1 M3	68.6 M3	68.0 M3

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Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH700 L6ARDP70U	



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Testing Services**		Aid Compatibility RF Emis Berry® Smartphone mode V		Page 179 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 5:44:46 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_high_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 15.6 V/m; Power Drift = -0.316 dB Maximum value of Total (measured) = 22.7 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 52.5 V/m

Probe Modulation Factor = 2.90

Device Reference Point: 0.000, 0.000, -6.30 mm

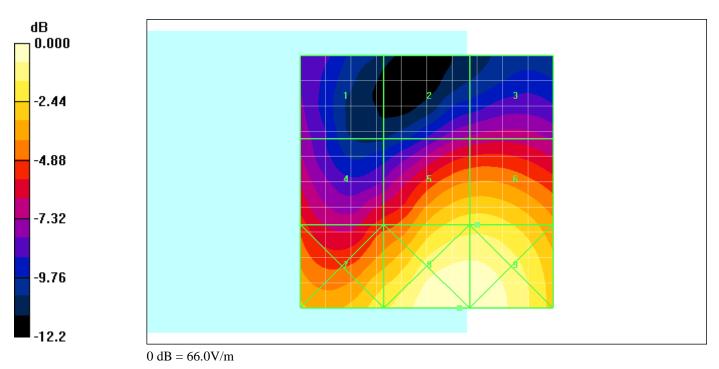
Reference Value = 15.6 V/m; Power Drift = -0.316 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
27.4 M4	29.4 M4	30.5 M4
Grid 4	Grid 5	Grid 6
36.2 M4	52.4 M3	52.5 M3
Grid 7	Grid 8	Grid 9

Peak E-field in V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 181 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 182 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	2W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 5:52:09 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_low_chan_Telecoil_Center

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 13.5 V/m; Power Drift = -0.186 dB Maximum value of Total (measured) = 23.7 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 47.8 V/m

Probe Modulation Factor = 2.90

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 13.5 V/m; Power Drift = -0.186 dB

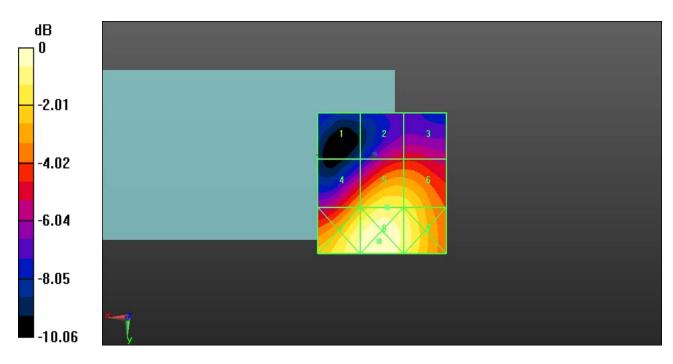
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
34.2 M4	32.8 M4	29.7 M4
Grid 4	Grid 5	Grid 6
36.9 M4	45.5 M4	48.4 M3
30.7 114	75.5 117	1011 1115
Grid 7	Grid 8	Grid 9

Peak E-field in V/m

 $0 \ dB = 68.9 V/m$

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Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 185 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 6:55:12 PM

Test Laboratory: RIM Testing Services

HAC_E_CDMA800_low_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 30.4 V/m; Power Drift = 0.179 dB Maximum value of Total (measured) = 27.0 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 27.3 V/m

Probe Modulation Factor = 1.01

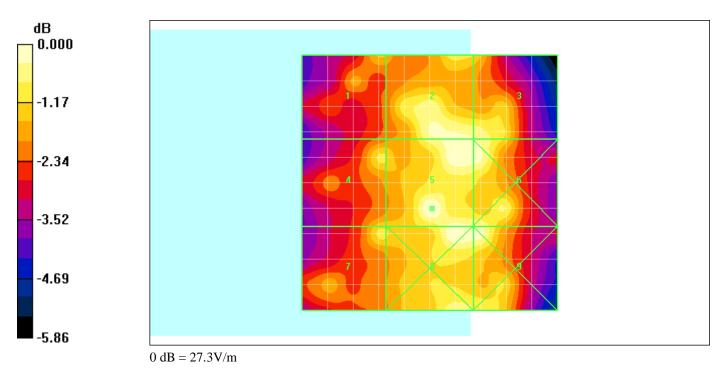
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 30.4 V/m; Power Drift = 0.179 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
23.1 M4	26.5 M4	26.3 M4
Grid 4	Grid 5	Grid 6
24.2 M4	27.3 M4	26.8 M4
Grid 7	Grid 8	Grid 9
24.2 M4	27.2 M4	26.7 M4

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Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			
Test 12-19, 2011 28 Mar 01 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C	
['est	Report No 2-19, 2011 RTS-2605-1102-02A	Rest Report No FCC ID 2-19, 2011 RTS-2605-1102-02A L6ARDH70C

Date/Time: 1/19/2011 6:59:51 PM

Test Laboratory: RIM Testing Services

HAC_E_CDMA800_mid_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 34.5 V/m; Power Drift = -0.044 dB Maximum value of Total (measured) = 27.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 27.3 V/m

Probe Modulation Factor = 1.01

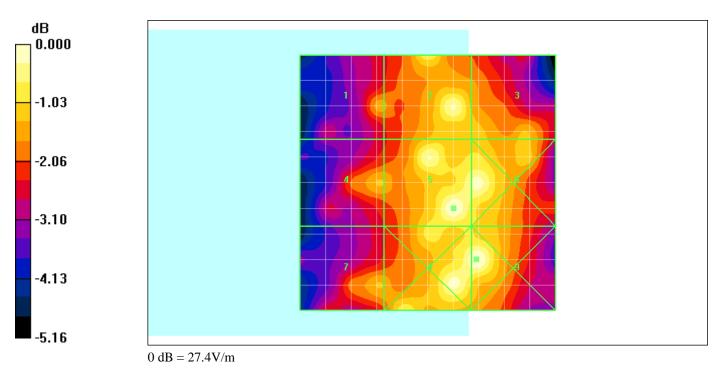
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 34.5 V/m; Power Drift = -0.044 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
23.0 M4	26.5 M4	23.9 M4
Grid 4	Grid 5	Grid 6
23.5 M4	27.3 M4	26.8 M4
Grid 7	Grid 8	Grid 9
23.5 M4	26.9 M4	27.4 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 190 (286)
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Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 191 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70C	W
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 7:04:41 PM

Test Laboratory: RIM Testing Services

HAC_E_CDMA800_high_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 29.1 V/m; Power Drift = -0.074 dB Maximum value of Total (measured) = 26.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 26.4 V/m

Probe Modulation Factor = 1.01

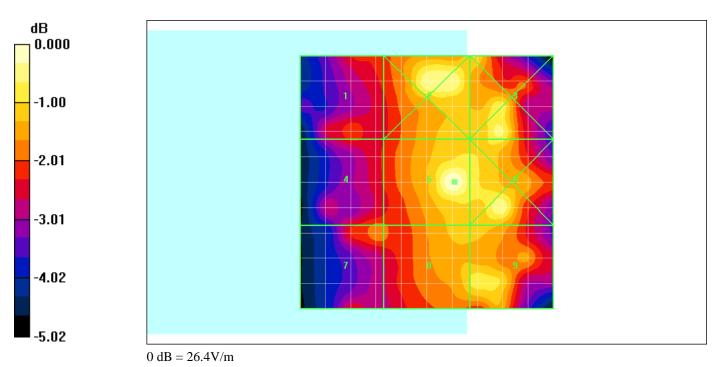
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 29.1 V/m; Power Drift = -0.074 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
20.9 M4	25.4 M4	24.8 M4
Grid 4	Grid 5	Grid 6
21.3 M4	26.4 M4	25.3 M4
Grid 7	Grid 8	Grid 9
21.7 M4	23.6 M4	24.1 M4

Testing Services ^{**}	DocumentAnnex A to Hearing Aid Compatibility RF Emissions TestPageReport for the BlackBerry® Smartphone model193 (286)RDH71CW/RDP71UW			
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW Feb. 28-Mar. 01, 2011 L6ARDP70UW			



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 7:10:17 PM

Test Laboratory: RIM Testing Services

 $HAC_E_CDMA800_mid_chan_Telecoil_Center$

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 30.6 V/m; Power Drift = 0.063 dB Maximum value of Total (measured) = 27.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 27.1 V/m

Probe Modulation Factor = 1.01

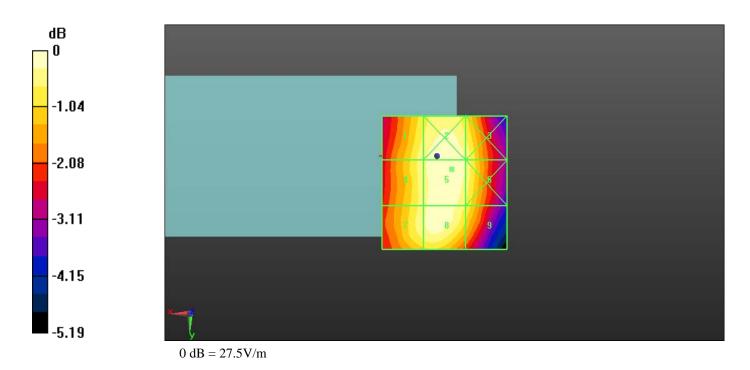
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 30.6 V/m; Power Drift = 0.063 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	V/m	
Grid 1	Grid 2	Grid 3
22.7 M4	26.9 M4	26.7 M4
Grid 4	Grid 5	Grid 6
23.0 M4	27.1 M4	27.1 M4
Grid 7	Grid 8	Grid 9
23.5 M4	27.5 M4	27.4 M4

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Author Data	Dates of Test Report No FCC ID			
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	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



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Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 7:17:37 PM

Test Laboratory: RIM Testing Services

HAC_E_CDMA1900_low_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 20.5 V/m; Power Drift = -0.338 dB Maximum value of Total (measured) = 34.2 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 26.1 V/m

Probe Modulation Factor = 1.00

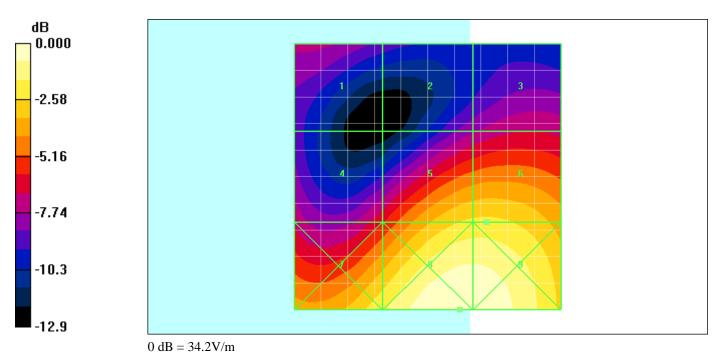
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.5 V/m; Power Drift = -0.338 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
14.5 M4	13.9 M4	15.6 M4
Grid 4	Grid 5	Grid 6
17.0 M4	26.0 M4	26.1 M4
Grid 7	Grid 8	Grid 9
27.6 M4	34.2 M4	34.0 M4

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Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011			



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Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 7:22:46 PM

Test Laboratory: RIM Testing Services

HAC_E_CDMA1900_mid_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 20.3 V/m; Power Drift = 0.032 dB Maximum value of Total (measured) = 32.4 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 25.0 V/m

Probe Modulation Factor = 1.00

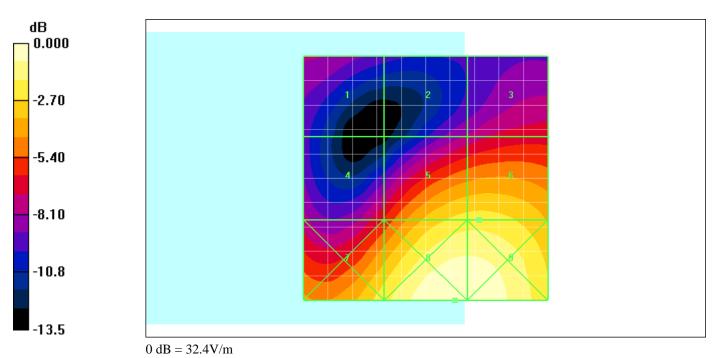
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.3 V/m; Power Drift = 0.032 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	n V/m	
Grid 1	Grid 2	Grid 3
13.0 M4	13.1 M4	15.1 M4
Grid 4	Grid 5	Grid 6
16.0 M4	24.8 M4	25.0 M4
Grid 7	Grid 8	Grid 9
25.5 M4	32.4 M4	32.1 M4

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Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



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Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
_	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Date/Time: 1/19/2011 7:27:06 PM

Test Laboratory: RIM Testing Services

HAC_E_CDMA1900_high_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 20.4 V/m; Power Drift = -0.143 dB Maximum value of Total (measured) = 31.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 24.8 V/m

Probe Modulation Factor = 1.00

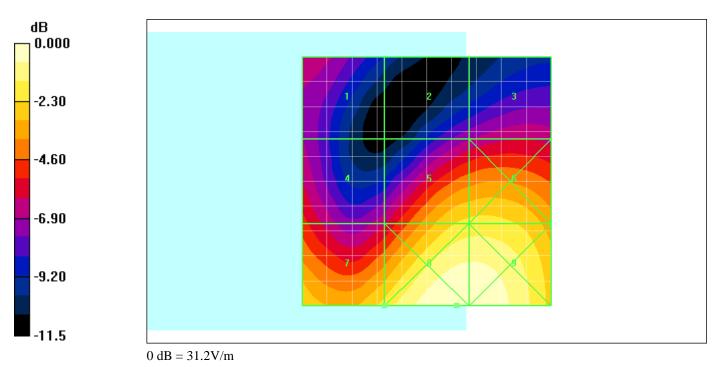
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.4 V/m; Power Drift = -0.143 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
14.8 M4	14.0 M4	15.4 M4
Grid 4	Grid 5	Grid 6
17.6 M4	24.6 M4	24.9 M4
Grid 7	Grid 8	Grid 9
24.8 M4	31.2 M4	31.0 M4

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Date/Time: 1/19/2011 7:33:46 PM

Test Laboratory: RIM Testing Services

HAC_E_CDMA1900_low_chan_Telecoil_Center

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 18.9 V/m; Power Drift = -0.163 dB Maximum value of Total (measured) = 30.4 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 21.2 V/m

Probe Modulation Factor = 1.00

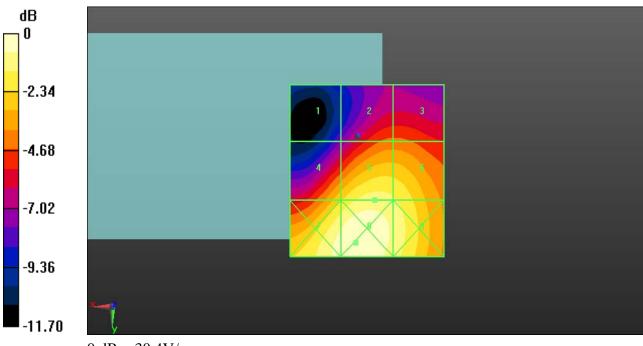
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 18.9 V/m; Power Drift = -0.163 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
15.1 M4	12.7 M4	12.8 M4
Grid 4	Grid 5	Grid 6
13.7 M4	21.1 M4	21.2 M4
Grid 7	Grid 8	Grid 9
24.0 M4	30.4 M4	30.1 M4

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 $0 \ dB = 30.4 V/m$

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Date/Time: 1/19/2011 8:20:04 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM850_low_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.080 A/m; Power Drift = 0.097 dB Maximum value of Total (measured) = 0.137 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.372 A/m

Probe Modulation Factor = 2.79

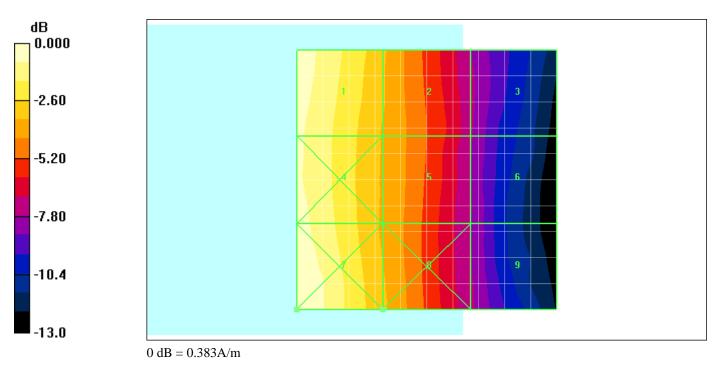
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.080 A/m; Power Drift = 0.097 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A	/m	
Grid 1	Grid 2	Grid 3
0.372 M4	0.263 M4	0.161 M4
Grid 4	Grid 5	Grid 6
0.362 M4	0.256 M4	0.159 M4
Grid 7	Grid 8	Grid 9
0.383 M4	0.263 M4	0.160 M4

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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV Feb. 28-Mar. 01, 2011 L6ARDP70UV L6ARDP70UV			



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Test Laboratory: RIM Testing Services

HAC_H_GSM850_mid_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.093 A/m; Power Drift = -0.224 dB Maximum value of Total (measured) = 0.160 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.417 A/m

Probe Modulation Factor = 2.79

Device Reference Point: 0.000, 0.000, -6.30 mm

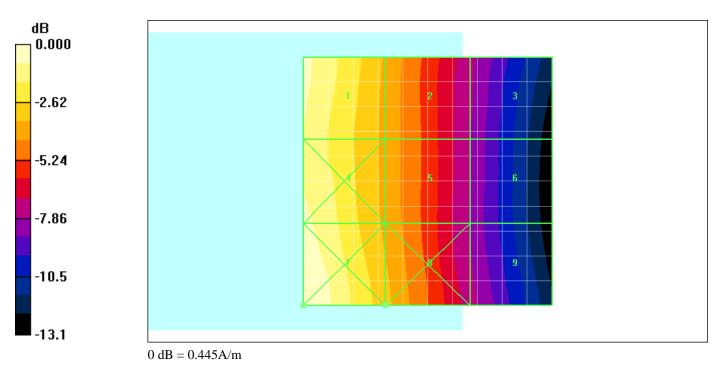
Reference Value = 0.093 A/m; Power Drift = -0.224 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.417 M4	0.294 M4	0.187 M4
Grid 4	Grid 5	Grid 6
0.412 M4	0.292 M4	0.182 M4
Grid 7	Grid 8	Grid 9
0.445 M4	0.309 M4	0.190 M4

Peak H-field in A/m

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Test Laboratory: RIM Testing Services

HAC_H_GSM850_high_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.115 A/m; Power Drift = 0.070 dB Maximum value of Total (measured) = 0.191 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.533 A/m

Probe Modulation Factor = 2.79

Device Reference Point: 0.000, 0.000, -6.30 mm

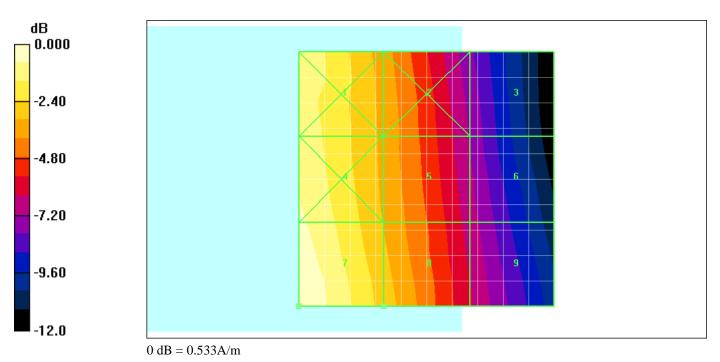
Reference Value = 0.115 A/m; Power Drift = 0.070 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.487 M3	0.360 M4	0.231 M4
Grid 4	Grid 5	Grid 6
0.498 M3	0.368 M4	0.245 M4
Grid 7	Grid 8	Grid 9
0.533 M3	0.390 M4	0.259 M4

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Date/Time: 1/19/2011 8:35:34 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM850_high_chan_Telecoil_Center

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.116 A/m; Power Drift = -0.077 dB Maximum value of Total (measured) = 0.202 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.562 A/m

Probe Modulation Factor = 2.79

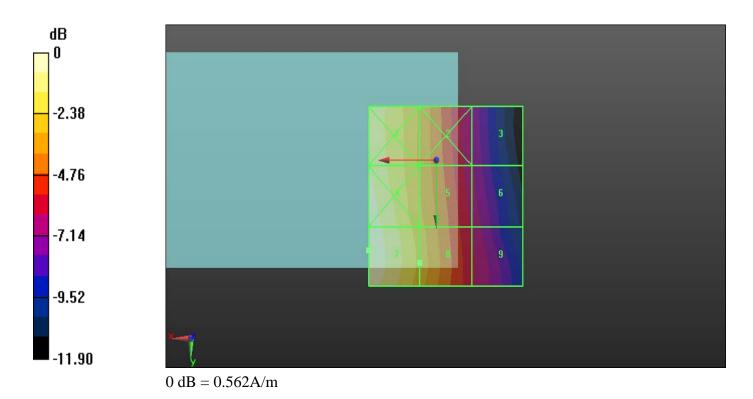
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.116 A/m; Power Drift = -0.077 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.509 M3	0.385 M4	0.258 M4
Grid 4	Grid 5	Grid 6
0.515 M3	0.395 M4	0.270 M4
Grid 7	Grid 8	Grid 9
0.562 M3	0.421 M4	0.282 M4

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Date/Time: 1/19/2011 8:41:39 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM1900_low_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.065 A/m; Power Drift = 0.234 dB Maximum value of Total (measured) = 0.080 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.152 A/m

Probe Modulation Factor = 2.52

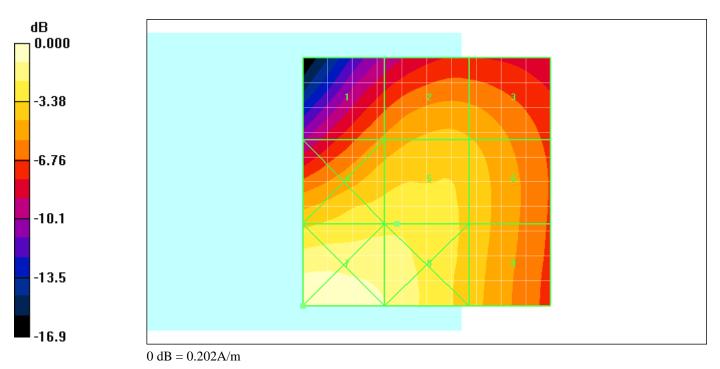
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.065 A/m; Power Drift = 0.234 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.109 M4	0.125 M4	0.122 M4
Grid 4	Grid 5	Grid 6
0.151 M3	0.152 M3	0.132 M4
Grid 7	Grid 8	Grid 9
0.202 M3	0.178 M3	0.132 M4

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Test Laboratory: RIM Testing Services

HAC_H_GSM1900_mid_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.066 A/m; Power Drift = 0.052 dB Maximum value of Total (measured) = 0.082 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.155 A/m

Probe Modulation Factor = 2.52

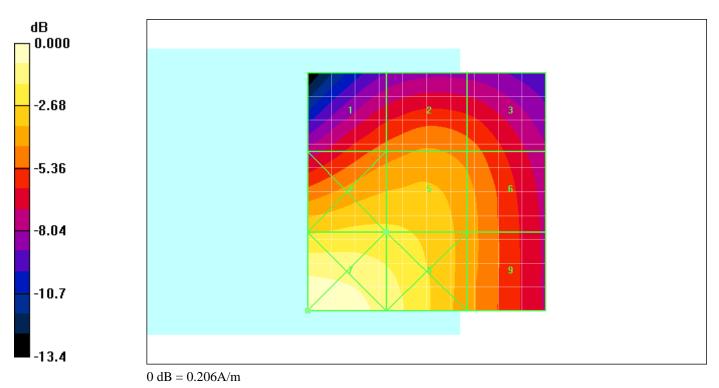
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.066 A/m; Power Drift = 0.052 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.117 M4	0.125 M4	0.117 M4
Grid 4	Grid 5	Grid 6
0.156 M3	0.155 M3	0.130 M4
Grid 7	Grid 8	Grid 9
0.206 M3	0.178 M3	0.130 M4

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Author Data	Dates of Test Report No FCC ID			
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Test Laboratory: RIM Testing Services

HAC_H_GSM1900_high_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.061 A/m; Power Drift = -0.032 dB Maximum value of Total (measured) = 0.091 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.159 A/m

Probe Modulation Factor = 2.52

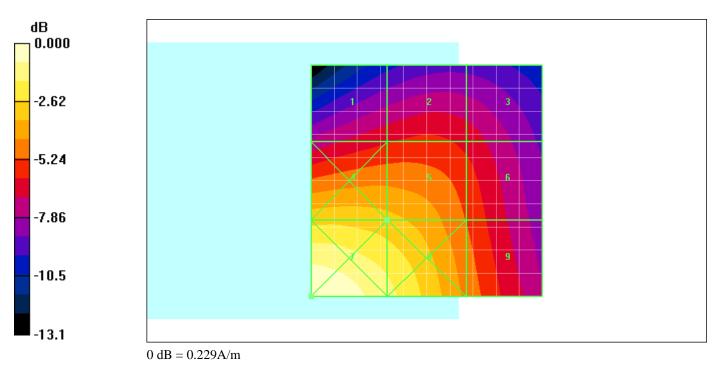
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.061 A/m; Power Drift = -0.032 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.113 M4	0.117 M4	0.110 M4
Grid 4	Grid 5	Grid 6
0.165 M3	0.159 M3	0.125 M4
Grid 7	Grid 8	Grid 9
0.229 M3	0.194 M3	0.136 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			
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Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
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Date/Time: 1/19/2011 8:56:42 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM1900_high_chan_Telecoil_Center

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.061 A/m; Power Drift = -0.076 dB Maximum value of Total (measured) = 0.087 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.153 A/m

Probe Modulation Factor = 2.52

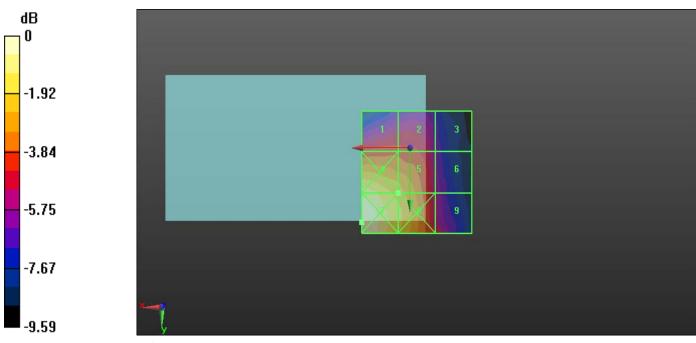
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.061 A/m; Power Drift = -0.076 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A	A/m	
Grid 1	Grid 2	Grid 3
0.103 M4	0.111 M4	0.111 M4
Grid 4	Grid 5	Grid 6
0.153 M3	0.153 M3	0.133 M4
Grid 7	Grid 8	Grid 9
0.220 M3	0.199 M3	0.146 M3

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 $0 \ dB = 0.220 A/m$

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Date/Time: 1/19/2011 9:04:35 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA800_low_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.035 A/m; Power Drift = -0.804 dB Maximum value of Total (measured) = 0.059 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.057 A/m

Probe Modulation Factor = 1.01

Device Reference Point: 0.000, 0.000, -6.30 mm

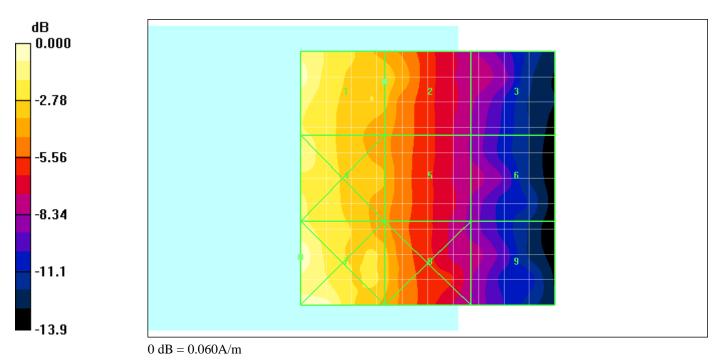
Reference Value = 0.035 A/m; Power Drift = -0.804 dB

Peak H-field in A/m

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.057 M4	0.041 M4	0.025 M4
Grid 4	Grid 5	Grid 6
0.055 M4	0.040 M4	0.025 M4
Grid 7	Grid 8	Grid 9
0.060 M4	0.041 M4	0.025 M4

Testing Services ^{**}	DocumentPageAnnex A to Hearing Aid Compatibility RF Emissions TestPageReport for the BlackBerry® Smartphone model235 (286)RDH71CW/RDP71UW235 (286)			
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Date/Time: 1/19/2011 9:08:52 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA800_mid_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 836.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.035 A/m; Power Drift = -0.904 dB Maximum value of Total (measured) = 0.053 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.051 A/m

Probe Modulation Factor = 1.01

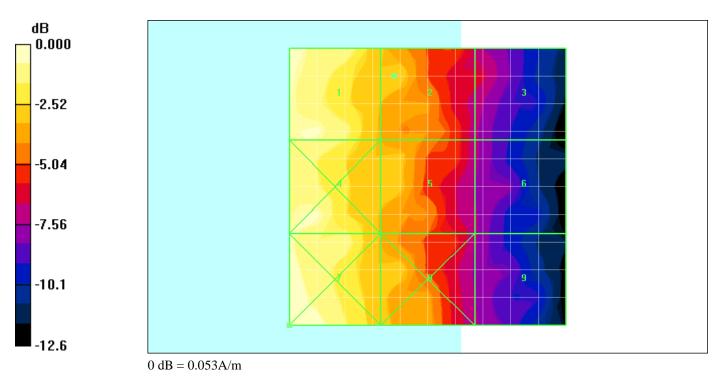
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.035 A/m; Power Drift = -0.904 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.051 M4	0.039 M4	0.026 M4
Grid 4	Grid 5	Grid 6
0.050 M4	0.038 M4	0.023 M4
Grid 7	Grid 8	Grid 9
0.053 M4	0.039 M4	0.023 M4

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Date/Time: 1/19/2011 9:14:16 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA800_high_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 848.52 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.034 A/m; Power Drift = 1.04 dB Maximum value of Total (measured) = 0.062 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.053 A/m

Probe Modulation Factor = 1.01

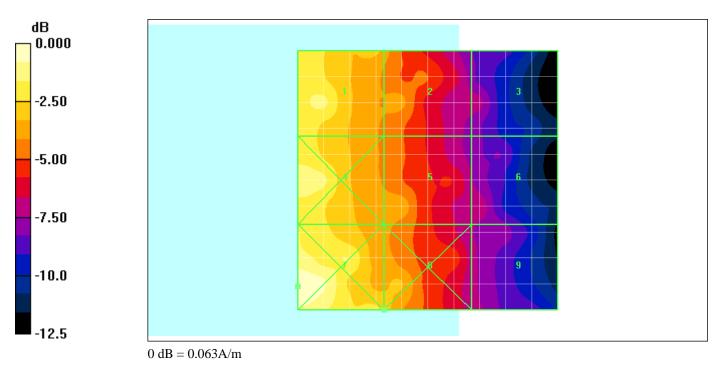
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.034 A/m; Power Drift = 1.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.053 M4	0.042 M4	0.028 M4
Grid 4	Grid 5	Grid 6
0.056 M4	0.042 M4	0.029 M4
Grid 7	Grid 8	Grid 9
0.063 M4	0.046 M4	0.028 M4

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Date/Time: 1/19/2011 9:20:14 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA800_low_chan_Telecoil_Center

DUT: BlackBerry Smartphone

Communication System: CDMA 800; Frequency: 824.7 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.035 A/m; Power Drift = -0.835 dB Maximum value of Total (measured) = 0.057 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.053 A/m

Probe Modulation Factor = 1.01

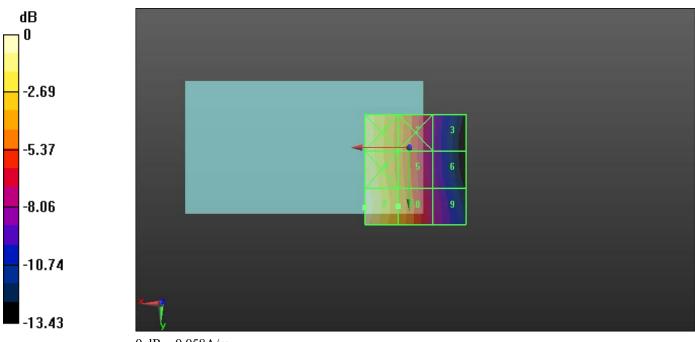
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.035 A/m; Power Drift = -0.835 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.053 M4	0.039 M4	0.027 M4
Grid 4	Grid 5	Grid 6
0.056 M4	0.039 M4	0.027 M4
Grid 7	Grid 8	Grid 9
0.058 M4	0.040 M4	0.026 M4

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 $0 \ dB = 0.058 \text{A/m}$

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Date/Time: 1/19/2011 9:26:27 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA1900_low_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1851.25 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.032 A/m; Power Drift = 0.232 dB Maximum value of Total (measured) = 0.038 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.031 A/m

Probe Modulation Factor = 1.08

Device Reference Point: 0.000, 0.000, -6.30 mm

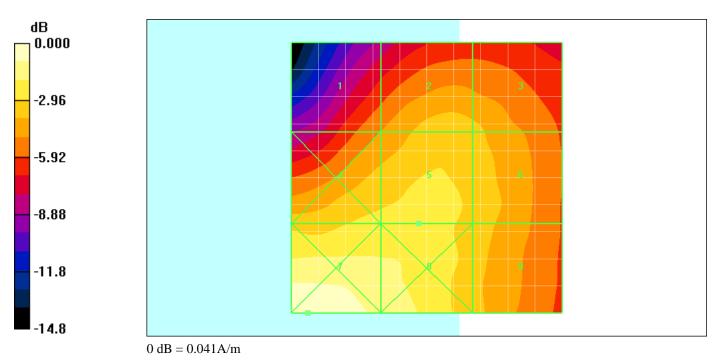
Reference Value = 0.032 A/m; Power Drift = 0.232 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.023 M4	0.028 M4	0.027 M4
Grid 4	Grid 5	Grid 6
0.030 M4	0.031 M4	0.028 M4
Grid 7	Grid 8	Grid 9
0.041 M4	0.036 M4	0.028 M4

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Date/Time: 1/19/2011 9:32:46 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA1900_mid_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.032 A/m; Power Drift = -0.069 dB Maximum value of Total (measured) = 0.040 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.032 A/m

Probe Modulation Factor = 1.08

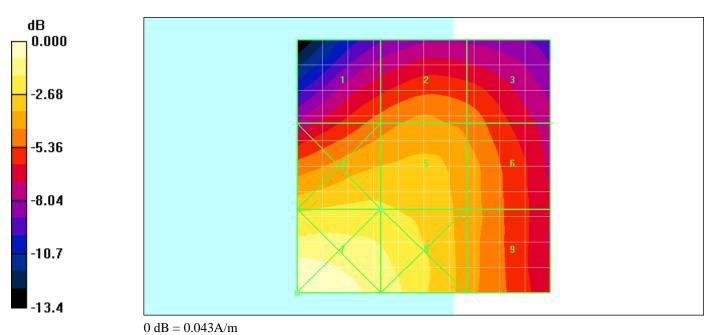
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.032 A/m; Power Drift = -0.069 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.024 M4	0.027 M4	0.025 M4
Grid 4	Grid 5	Grid 6
0.033 M4	0.032 M4	0.027 M4
Grid 7	Grid 8	Grid 9
0.043 M4	0.037 M4	0.027 M4

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Date/Time: 1/19/2011 9:37:14 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA1900_high_chan

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.030 A/m; Power Drift = -0.006 dB Maximum value of Total (measured) = 0.044 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the



dx=5mm, dy=5mm

Maximum value of peak Total field = 0.034 A/m

Probe Modulation Factor = 1.08

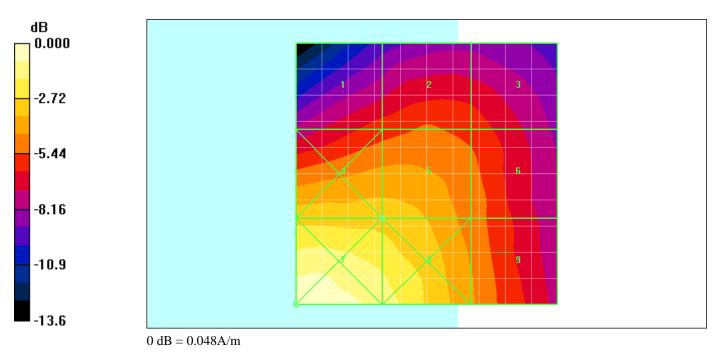
Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.030 A/m; Power Drift = -0.006 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.024 M4	0.026 M4	0.025 M4
Grid 4	Grid 5	Grid 6
0.034 M4	0.034 M4	0.027 M4
Grid 7	Grid 8	Grid 9
0.048 M4	0.041 M4	0.029 M4

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Date/Time: 1/19/2011 9:42:28 PM

Test Laboratory: RIM Testing Services

HAC_H_CDMA1900_high_chan_Telecoil_Center

DUT: BlackBerry Smartphone

Communication System: CDMA 1900; Frequency: 1908.5 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 SN6168; ; Calibrated: 3/12/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid:

dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.031 A/m; Power Drift = -0.179 dB Maximum value of Total (measured) = 0.042 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the

Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid:



Daoud Attayi

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.032 A/m

Probe Modulation Factor = 1.08

Device Reference Point: 0.000, 0.000, -6.30 mm

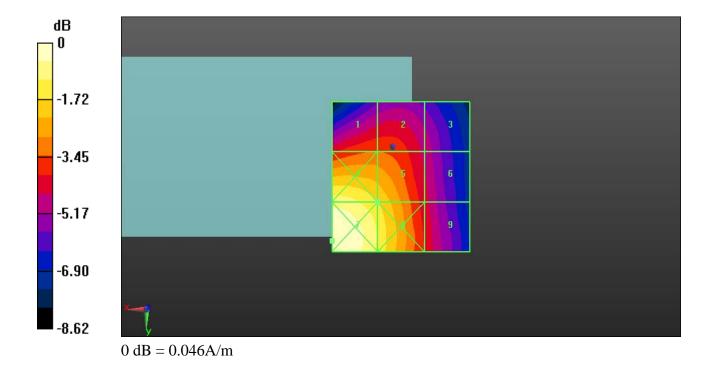
Reference Value = 0.031 A/m; Power Drift = -0.179 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1 Grid 2 Grid 3 0.023 M4 0.024 M4 0.023 M4 Grid 5 Grid 6 Grid 4 0.026 M4 0.032 M4 0.032 M4 Grid 7 Grid 8 Grid 9 0.046 M4 0.039 M4 0.027 M4

Peak H-field in A/m

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Date/Time: 3/1/2011 10:35:01 AM, Date/Time: 3/1/2011 10:40:03 AM, Date/Time: 3/1/2011 10:44:13 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_V

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency: 826.4

MHz, Frequency: 836.4 MHz, Frequency: 846.6 MHz;Communication System

PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 52.583 V/m

Probe Modulation Factor = 1.010

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Reference Value = 64.714 V/m; Power Drift = 0.01 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V	/111	
Grid 1	Grid 2	Grid 3
47.660 M4	52.032 M4	51.028 M4
Grid 4	Grid 5	Grid 6
48.222 M4	52.583 M4	51.734 M4
Grid 7	Grid 8	Grid 9
46.728 M4	51.373 M4	50.523 M4

Peak E-field in V/m

Cursor:

Total = 52.583 V/m E Category: M4 Location: -4.5, -4, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D -2007: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 52.821 V/m Probe Modulation Factor = 1.010 Device Reference Point: 0, 0, -6.3 mm Reference Value = 64.504 V/m; Power Drift = 0.01 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 259 (286)			
Author Data	Dates of Test Report No FCC ID				
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW Feb. 28-Mar. 01, 2011 L6ARDP70UW				

Peak	E-field	in	V/m
------	---------	----	-----

Grid 1	Grid 2	Grid 3
45.986 M4	52.317 M4	52.042 M4
Grid 4	Grid 5	Grid 6
46.920 M4	52.821 M4	52.685 M4
Grid 7	Grid 8	Grid 9
45.676 M4	51.678 M4	51.592 M4

Total = 52.821 V/m E Category: M4 Location: -5.5, -3.5, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D -2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm,

dy=5mm Maximum value of peak Total field = 61.736 V/m Probe Modulation Factor = 1.010 Device Reference Point: 0, 0, -6.3 mm Reference Value = 74.881 V/m; Power Drift = 0.08 dB

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 260 (286)		
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

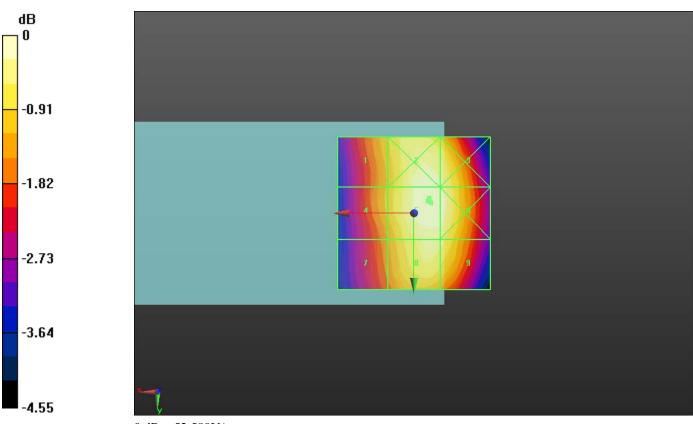
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in	V/m	
Grid 1	Grid 2	Grid 3
55.713 M4	60.679 M4	60.049 M4
Grid 4	Grid 5	Grid 6
54.712 M4	61.736 M4	61.043 M4
Grid 7	Grid 8	Grid 9
52.185 M4	58.806 M4	58.412 M4

Cursor:

Total = 61.736 V/m E Category: M4 Location: -5, -5, 8.7 mm

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 261 (286)		
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011	W		
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \ dB = 52.580 V/m$

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 262 (286)
Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CV Feb. 28-Mar. 01, 2011 L6ARDP70UV L6ARDP70UV			

Date/Time: 3/1/2011 10:49:29 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_V

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency: 846.6

MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15

mm from Probe Center to the Device Telecoil cent/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 60.388 V/m

Probe Modulation Factor = 1.010

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 263 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 75.486 V/m; Power Drift = -0.07 dB

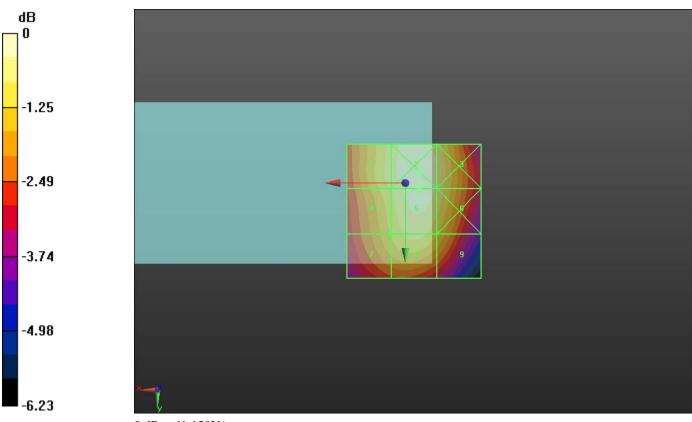
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V	V/m	
Grid 1	Grid 2	Grid 3
57.170 M4	61.145 M4	58.632 M4
Grid 4	Grid 5	Grid 6
56.145 M4	60.388 M4	57.980 M4
Grid 7	Grid 8	Grid 9
53.266 M4	56.485 M4	53.282 M4

Cursor:

Total = 61.145 V/m E Category: M4 Location: -5.2, -4, 8.7 mm

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 264 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 61.150 V/m

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 265 (286)
Author Data Daoud Attayi	Dates of Test Report No FCC ID Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C Feb. 28-Mar. 01, 2011 L6ARDP70U L6ARDP70U			

Date/Time: 3/1/2011 11:02:11 AM, Date/Time: 3/1/2011 11:07:14 AM, Date/Time: 3/1/2011 11:11:37 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_II

DUT: BlackBerry Smartphone; Type

Communication System: WCDMA FDD II; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency:

1852.4 MHz, Frequency: 1880 MHz, Frequency: 1907.6 MHz;Communication

System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 30.010 V/m

Probe Modulation Factor = 1.120

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 266 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 19.777 V/m; Power Drift = 0.03 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V	V/m	
Grid 1	Grid 2	Grid 3
18.239 M4	20.904 M4	22.582 M4
Grid 4	Grid 5	Grid 6
20.513 M4	29.636 M4	30.010 M4
Grid 7	Grid 8	Grid 9
32.994 M4	37.039 M4	36.418 M4

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 33.098 V/m Probe Modulation Factor = 1.120 Device Reference Point: 0, 0, -6.3 mm Reference Value = 22.386 V/m; Power Drift = -0.06 dB **Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 267 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH700			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	vv

Peak E-field	in V/m
--------------	--------

Grid 1	Grid 2	Grid 3
19.707 M4	22.672 M4	25.026 M4
Grid 4	Grid 5	Grid 6
21.951 M4	32.621 M4	33.098 M4
Grid 7	Grid 8	Grid 9
34.980 M4	40.051 M4	39.598 M4

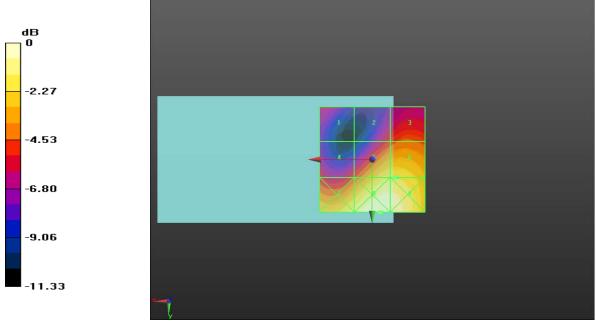
Device E-Field measurement with ER probe/E Scan - ER3D -2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm,

dy=5mm Maximum value of peak Total field = 35.333 V/m Probe Modulation Factor = 1.120 Device Reference Point: 0, 0, -6.3 mm Reference Value = 26.282 V/m; Power Drift = 0.0066 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 268 (286)
Author Data	Dates of Test Report No FCC ID			
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70C Feb. 28-Mar. 01, 2011 L6ARDP70U L6ARDP70U			

Peak E-field in V	/m	
Grid 1	Grid 2	Grid 3
21.198 M4	23.468 M4	25.389 M4
Grid 4	Grid 5	Grid 6
24.630 M4	35.187 M4	35.333 M4
Grid 7	Grid 8	Grid 9
37.167 M4	42.179 M4	41.288 M4



 $0 \ dB = 37.040 V/m$

Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			269 (286)	
Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW				
	Report for the Black	Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Report No Jan. 12-19, 2011 RTS-2605-1102-02A	Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW Dates of Test Report No FCC ID L6ARDH70C	

Date/Time: 3/1/2011 11:25:52 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_II

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD II; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency:

1907.6 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011
 - Modulation Compensation: Not calibrated
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 40.243 V/m Probe Modulation Factor = 1.120 Device Reference Point: 0, 0, -6.3 mm

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 270 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

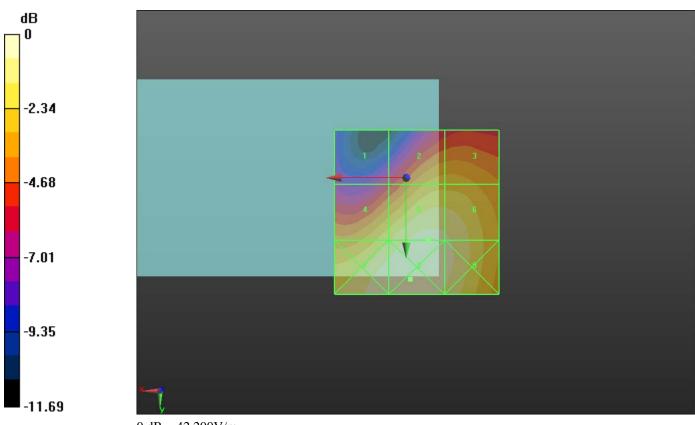
Reference Value = 25.749 V/m; Power Drift = 0.19 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/	m	
Grid 1	Grid 2	Grid 3
21.556 M4	31.392 M4	31.432 M4
Grid 4	Grid 5	Grid 6
35.136 M4	40.243 M4	39.305 M4
Grid 7	Grid 8	Grid 9
41.463 M4	42.201 M4	39.966 M4

Peak E-field in V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 271 (286)	
Author Data	Dates of Test	Report No	FCC ID		
Daoud Attayi	Jan. 12-19, 2011	W			
	Feb. 28-Mar. 01, 2011				



0 dB = 42.200 V/m

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 272 (286)		
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	

Date/Time: 3/1/2011 11:49:04 AM, Date/Time: 3/1/2011 11:55:01 AM, Date/Time: 3/1/2011 12:01:51 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band V

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency: 826.4

MHz, Frequency: 836.4 MHz, Frequency: 846.6 MHz;Communication System

PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 -

2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.106 A/m

Probe Modulation Factor = 0.990

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 273 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Reference Value = 0.062 A/m; Power Drift = 0.08 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A	A/m	
Grid 1	Grid 2	Grid 3
0.106 M4	0.076 M4	0.046 M4
Grid 4	Grid 5	Grid 6
0.105 M4	0.075 M4	0.046 M4
Grid 7	Grid 8	Grid 9
0.114 M4	0.081 M4	0.050 M4

Device H-Field meausrement with H3DV6 probe/H Scan -H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm Maximum value of peak Total field = 0.109 A/m Probe Modulation Factor = 0.990 Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.065 A/m; Power Drift = -0.07 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 274 (286)	
Author Data	Dates of Test	Report No	FCC ID		
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW				
	Feb. 28-Mar. 01, 2011	Feb. 28-Mar. 01, 2011 L6ARDP70UW			

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.109 M4	0.080 M4	0.050 M4
Grid 4	Grid 5	Grid 6
0.105 M4	0.077 M4	0.048 M4
Grid 7	Grid 8	Grid 9
0.114 M4	0.082 M4	0.051 M4

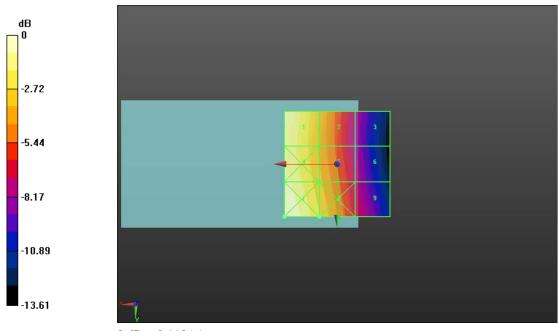
Device H-Field meausrement with H3DV6 probe/H Scan -H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm Maximum value of peak Total field = 0.120 A/m Probe Modulation Factor = 0.990 Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.077 A/m; Power Drift = 0.11 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Document Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 275 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW E. L. 20 M. 01 2011			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.120 M4	0.089 M4	0.055 M4
Grid 4	Grid 5	Grid 6
0.122 M4	0.092 M4	0.060 M4
Grid 7	Grid 8	Grid 9
0.134 M4	0.099 M4	0.065 M4



Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 276 (286)			
Author Data	Dates of Test Report No FCC ID				
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW				
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W	

Date/Time: 3/1/2011 12:05:47 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band V

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD V; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency: 846.6

MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 -2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.113 A/m Probe Modulation Factor = 0.990 Device Reference Point: 0, 0, -6.3 mm

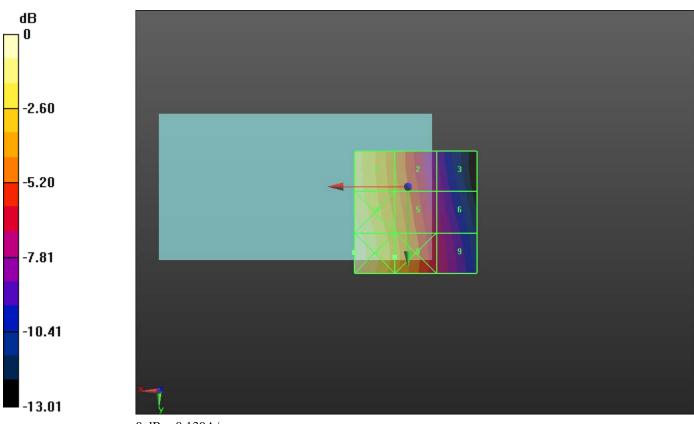
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 277 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Reference Value = 0.077 A/m; Power Drift = -0.06 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A	A/m	
Grid 1	Grid 2	Grid 3
0.113 M4	0.082 M4	0.053 M4
Grid 4	Grid 5	Grid 6
0.124 M4	0.089 M4	0.057 M4
Grid 7	Grid 8	Grid 9
0.127 M4	0.092 M4	0.060 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 278 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \, dB = 0.130 \text{A/m}$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 279 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	

Date/Time: 3/1/2011 12:17:38 PM, Date/Time: 3/1/2011 12:21:56 PM, Date/Time: 3/1/2011 12:39:06 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band II

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD II; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency:

1852.4 MHz, Frequency: 1880 MHz, Frequency: 1907.6 MHz;Communication

System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 -

2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.096 A/m

Probe Modulation Factor = 1.120

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 280 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Reference Value = 0.092 A/m; Power Drift = -0.16 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	A/m	
Grid 1	Grid 2	Grid 3
0.075 M4	0.081 M4	0.077 M4
Grid 4	Grid 5	Grid 6
0.096 M4	0.096 M4	0.086 M4
Grid 7	Grid 8	Grid 9
0.124 M4	0.111 M4	0.088 M4

Device H-Field meausrement with H3DV6 probe/H Scan -H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

dx=5mm, dy=5mm Maximum value of peak Total field = 0.105 A/m Probe Modulation Factor = 1.120 Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.097 A/m; Power Drift = -0.09 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 281 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W

Peak H-field in A	A/m	_
Grid 1	Grid 2	Grid 3
0.079 M4	0.085 M4	0.082 M4
Grid 4	Grid 5	Grid 6
0.105 M4	0.105 M4	0.095 M4
Grid 7	Grid 8	Grid 9
0.140 M4	0.124 M4	0.097 M4

Device H-Field meausrement with H3DV6 probe/H Scan -H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid:

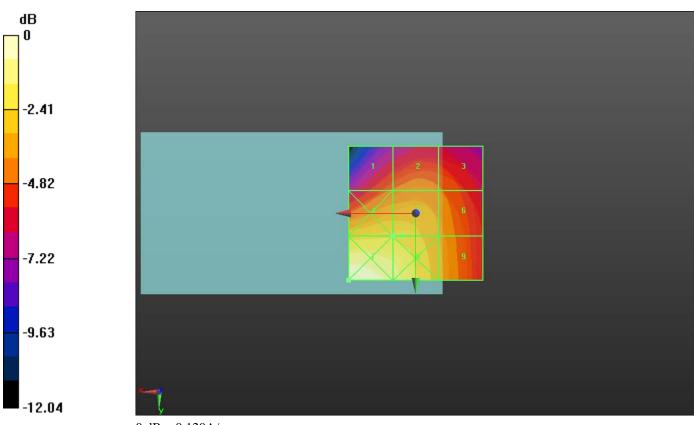
dx=5mm, dy=5mm Maximum value of peak Total field = 0.112 A/m Probe Modulation Factor = 1.120 Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.100 A/m; Power Drift = 0.07 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 282 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70C L6ARDP70U	

Peak H-field in A	A/m	
Grid 1	Grid 2	Grid 3
0.088 M4	0.092 M4	0.088 M4
Grid 4	Grid 5	Grid 6
0.113 M4	0.112 M4	0.095 M4
Grid 7	Grid 8	Grid 9
0.149 M4	0.131 M4	0.098 M4

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Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 283 (286)
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 RTS-2605-1102-02A L6ARDH70CW			CW
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



 $0 \, dB = 0.120 \, A/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDH71CW/RDP71UW			Page 284 (286)
Author Data Daoud Attayi	Dates of Test Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	Report No RTS-2605-1102-02A	FCC ID L6ARDH70C L6ARDP70U	

Date/Time: 3/1/2011 12:45:24 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band II

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD II; Communication System Band:

Exported from older format (data unavailable - please correct).; Frequency:

1907.6 MHz;Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 11/18/2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn881; Calibrated: 4/19/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 -2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.122 A/m Probe Modulation Factor = 1.120 Device Reference Point: 0, 0, -6.3 mm

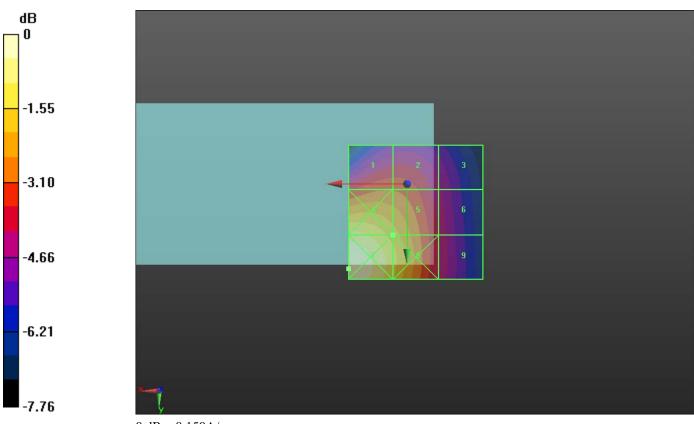
Testing Services™	Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 285 (286)		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011 Feb. 28-Mar. 01, 2011	RTS-2605-1102-02A	L6ARDH70CW L6ARDP70UW	

Reference Value = 0.102 A/m; Power Drift = -0.16 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in	n A/m	
Grid 1	Grid 2	Grid 3
0.105	0.104	0.089
Μ	Μ	Μ
4	4	4
Grid 4	Grid 5	Grid 6
0.137	0.122	0.093
Μ	Μ	Μ
4	4	4
Grid 7	Grid 8	Grid 9
0.153	0.129	0.094
Μ	Μ	Μ
4	4	4

Testing Services™	Document Annex A to Hearing Report for the Black RDH71CW/RDP71UV	Page 286 (286)		
Author Data	Dates of Test	Report No	FCC ID	
Daoud Attayi	Jan. 12-19, 2011	RTS-2605-1102-02A	L6ARDH70CW	
	Feb. 28-Mar. 01, 2011		L6ARDP70U	W



0 dB = 0.150 A/m